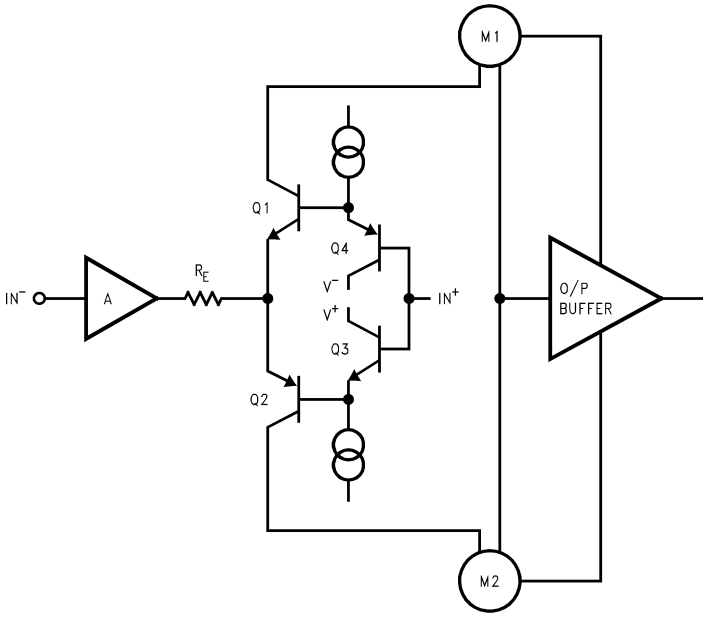
LM7171 Very High Speed, High Output Current, Voltage Feedback Amplifier

1 Features

- Typical values unless otherwise noted
- Easy-to-use voltage-feedback topology
- Very high slew rate: 4100V/µs
- Wide unity-gain bandwidth: 200MHz
- −3dB frequency at A_V = +2: 220MHz
- Low supply current: 6.5mA
- High open-loop gain: 85dB
- High output current: 100mA
- Differential gain and phase: 0.01%, 0.02º
- Specified for ±15V and ±5V operation

2 Applications

- HDSL and ADSL drivers
- Multimedia broadcast systems
- Professional video cameras
- Video amplifiers
- Copiers, scanners, fax
- HDTV amplifiers
- Pulse amplifiers and peak detectors
- CATV and fiber optics signal processing



Note: M1 and M2 are current mirrors.

Simplified Schematic Diagram

3 Description

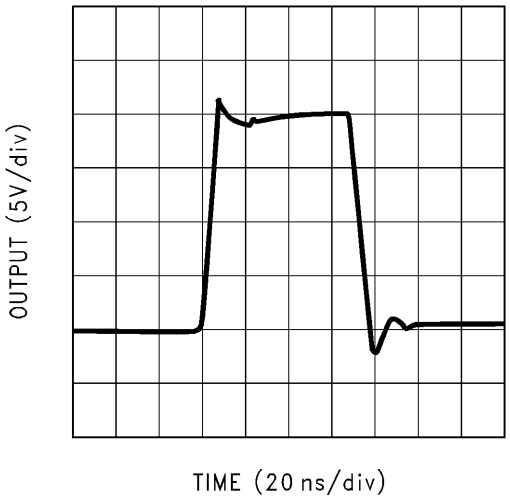
The LM7171 is a high-speed voltage-feedback amplifier that has the slewing characteristic of a current-feedback amplifier, but can be used in all traditional voltage-feedback amplifier configurations. The LM7171 is stable for gains as low as +2 or −1. The device provides a very high slew rate at 4100V/µs and a wide unity-gain bandwidth of 200MHz, while consuming only 6.5mA of supply current. The LM7171 is an excellent choice for video and high-speed signal processing applications, such as HDSL and pulse amplifiers. With 100mA of output current, the LM7171 is used for video distribution, as a transformer driver, or as a laser diode driver.

Operation on ±15V power supplies allows for large signal swings and provides greater dynamic range and signal-to-noise ratio. The LM7171 offers low SFDR and THD, which is excellent for ADC/DAC systems. In addition, the LM7171 is specified for ±5V operation for portable applications.

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
LM7171	D (SOIC, 8)	4.90mm × 6mm
	P (PDIP, 8)	9.81mm × 9.43mm

(1) For more information, see Section 9.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Large-Signal Pulse Response A_V = +2, V_S = ±15V

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Pin Configuration and Functions

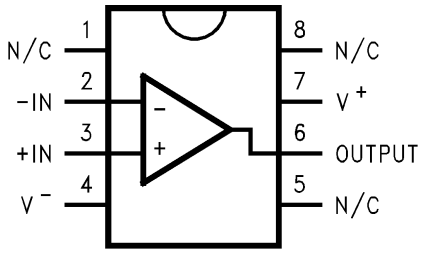

Figure 4-1. D Package, 8-Pin SOIC (Top View)

Table 4-1. Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	NC	—	No connection
2	–IN	Input	Inverting power supply
3	+IN	Input	Noninverting power supply
4	V–	Input	Supply voltage
5	NC	—	No connection
6	OUTPUT	Output	Output
7	V+	Input	Supply voltage
8	NC	—	No connection

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V_S	Supply voltage ($V^+ – V^–$)		36	V
VI	Differential input voltage(2)		±10	V
I_{SC}	Output current short to ground(3)		Continuous	A
T_J	Junction temperature(4)		150	℃

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) Input differential voltage is applied at V_S = ±15V.
(3) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.
(4) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{θJA}$, and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)}–T_A)/R_{θJA}$. All numbers apply for packages soldered directly into a PC board.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2500	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002(2)	±1500	V

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP155 states that 2500V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	TYP	MAX	UNIT
V_S	Supply voltage	5.5		36	V
T_A	Ambient temperature	−40		85	°C

5.4 Thermal Information

THERMAL METRIC(1)		LM7171			UNIT
		D (SOIC) A Version	D (SOIC) B Version	P (PDIP)	
		8 PINS	8 PINS	8 PINS	
$R_{θJA}$	Junction-to-ambient thermal resistance	122.5	172	108	℃/W
$R_{θJC(top)}$	Junction-to-case (top) thermal resistance	64.7	62.4	52.4	℃/W
$R_{θJB}$	Junction-to-board thermal resistance	65.9	55.7	51.9	℃/W
$Ψ_{JT}$	Junction-to-top characterization parameter	17.6	16.5	6.8	℃/W
$Ψ_{JB}$	Junction-to-board characterization parameter	65.1	55.1	51.1	℃/W
$R_{θJC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	℃/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

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5.5 Electrical Characteristics: ±15V

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OS}	Input offset voltage	LM7171A			0.2	1	mV
			T_A = –40°C to +85°C			4	
		LM7171B			0.2	3	
			T_A = –40°C to +85°C			7	
TCV_{OS}	Input offset voltage average drift				35		µV/°C
I_B	Input bias current				2.7	10	µA
		T_A = –40°C to +85°C				12	
I_{OS}	Input offset current				0.1	4	µA
		T_A = –40°C to +85°C				6	
R_{IN}	Input resistance	Common mode			320		MΩ
		Differential mode			18		
R_O	Open-loop output resistance				19		Ω
CMRR	Common-mode rejection ratio	LM7171A	V_{CM} = ±10V	85	105		dB
			V_{CM} = ±10V, T_A = –40°C to +85°C	80			
		LM7171B	V_{CM} = ±10V	75	105		
			V_{CM} = ±10V, T_A = –40°C to +85°C	70			
PSRR	Power supply rejection ratio	LM7171A	V_S = ±15V	85	90		dB
			V_S = ±15V, T_A = –40°C to +85°C	80			
		LM7171B	V_S = ±15V				
			V_S = ±15V, T_A = –40°C to +85°C				
V_{CM}	Input common-mode voltage	CMRR > 60dB			±13.35		V
A_V	Large-signal voltage gain	LM7171A	R_L = 1kΩ, V_{OUT} = ±5V	80	85		dB
			R_L = 1kΩ, V_{OUT} = ±5V, T_A = –40°C to +85°C	75			
			R_L = 100Ω, V_{OUT} = ±5V	75	81		
			R_L = 100Ω, V_{OUT} = ±5V, T_A = –40°C to +85°C	70			
		LM7171B	R_L = 1kΩ, V_{OUT} = ±5V	75	85		
			R_L = 1kΩ, V_{OUT} = ±5V, T_A = –40°C to +85°C	70			
			R_L = 100Ω, V_{OUT} = ±5V	70	81		
			R_L = 100Ω, V_{OUT} = ±5V, T_A = –40°C to +85°C	66			
V_O	Output swing	R_L = 1kΩ		13	13.3		V
			T_A = –40°C to +85°C	12.7			
		R_L = 1kΩ		–13	–13.2		
			T_A = –40°C to +85°C	–12.7			
		R_L = 100Ω		10.5	11.8		
			T_A = –40°C to +85°C	9.5			
		R_L = 100Ω		–9.5	–10.5		
			T_A = –40°C to +85°C	–9			

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5.5 Electrical Characteristics: ±15V (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
	Output current (open loop)	Sourcing, R_L = 100Ω		105	118		mA
			T_A = –40°C to +85°C	95			
		Sinking, R_L = 100Ω		95	105		
			T_A = –40°C to +85°C	90			
	Output current (in linear region)	Sourcing, R_L = 100Ω			100		
		Sinking, R_L = 100Ω			100		
I_{SC}	Output short-circuit current	Sourcing			140		
		Sinking			135		
I_S	Supply current				6.5	8.5	
						9.5	
SR	Slew rate	A_V = +2, V_{IN} = 13V_{PP}			4100		V/µs
		A_V = +2, V_{IN} = 10V_{PP}			3100		
	Unity-gain bandwidth	LM7171A			160		MHz
		LM7171B			200		
	−3dB frequency	A_V = +2			220		MHz
φ_m	Phase margin				50		Deg
t_s	Settling time (0.1%)	A_V = −1, V_{OUT} = ±5V, R_L = 500Ω	LM7171A		16		ns
			LM7171B		42		ns
t_p	Propagation delay	A_V = −2, V_{IN} = ±1V, R_L = 500Ω			5		ns
HD2	Second harmonic distortion	LM7171A	f_{IN} = 10kHz		–123		dBc
			f_{IN} = 5MHz		–75		
		LM7171B	f_{IN} = 10kHz		–110		
			f_{IN} = 5MHz		–75		
HD3	Third harmonic distortion	LM7171A	f_{IN} = 10kHz		–133		dBc
			f_{IN} = 5MHz		–88		
		LM7171B	f_{IN} = 10kHz		–115		
			f_{IN} = 5MHz		–55		
e_n	Input-referred voltage noise	f = 10kHz	LM7171A		8.5		nV/√Hz
			LM7171B		14		
i_n	Input-referred current noise	f = 10kHz	LM7171A		1		pA/√Hz
			LM7171B		1.5		

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5.6 Electrical Characteristics: ±5V

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OS}	Input offset voltage	LM7171A			0.3	1.5	mV
			T_A = –40°C to +85°C			4	
		LM7171B			0.3	3.5	
			T_A = –40°C to +85°C			7	
TCV_{OS}	Input offset voltage average drift				35		µV/°C
I_B	Input bias current				3.3	10	µA
		T_A = –40°C to +85°C				12	
I_{OS}	Input offset current				0.1	4	µA
		T_A = –40°C to +85°C				6	
R_{IN}	Input resistance	Common mode			250		MΩ
		Differential mode			18		
R_O	Open-loop output resistance				18		Ω
CMRR	Common-mode rejection ratio	LM7171A	V_{CM} = ±2.5V	80	104		dB
			V_{CM} = ±2.5V, T_A = –40°C to +85°C	75			
		LM7171B	V_{CM} = ±2.5V	70	104		
			V_{CM} = ±2.5V, T_A = –40°C to +85°C	65			
PSRR	Power supply rejection ratio	LM7171A	V_S = ±5V	85	90		dB
			V_S = ±5V, T_A = –40°C to +85°C	80			
		LM7171B	V_S = ±5V	75	90		
			V_S = ±5V, T_A = –40°C to +85°C	70			
V_{CM}	Input common-mode voltage range	CMRR > 60dB			±3.2		V
A_V	Large-signal voltage gain	LM7171A	R_L = 1kΩ, V_{OUT} = ±1V	75	78		dB
			R_L = 1kΩ, V_{OUT} = ±1V, T_A = –40°C to +85°C	70			
			R_L = 100Ω, V_{OUT} = ±1V	72	76		
			R_L = 100Ω, V_{OUT} = ±1V, T_A = –40°C to +85°C	67			
		LM7171B	R_L = 1kΩ, V_{OUT} = ±1V	70	78		
			R_L = 1kΩ, V_{OUT} = ±1V, T_A = –40°C to +85°C	65			
			R_L = 100Ω, V_{OUT} = ±1V	68	76		
			R_L = 100Ω, V_{OUT} = ±1V, T_A = –40°C to +85°C	63			
V_O	Output swing	R_L = 1kΩ		3.2	3.4		V
				–3.2	–3.4		
			T_A = –40°C to +85°C	3			
				–3			
		R_L = 100Ω		2.9	3.1		
				–2.9	–3		
			T_A = –40°C to +85°C	2.8			
				–2.8			

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5.6 Electrical Characteristics: ±5V (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
	Output current (open loop)	Sourcing, R_L = 100Ω		29	31		mA
			T_A = –40°C to +85°C	28			
		Sinking, R_L = 100Ω		29	30		
			T_A = –40°C to +85°C	28			
	Output current (in linear region)	Sourcing, R_L = 100Ω			30		mA
		Sinking, R_L = 100Ω			31		
I_{SC}	Output short-circuit current	Sourcing			135		mA
		Sinking			100		
I_S	Supply current				6.2	8	mA
		T_A = –40°C to +85°C				9	
SR	Slew rate	A_V = +2, V_{IN} = 3.2V_{PP}	LM7171A		1200		V/µs
			LM7171B		950		
	Unity-gain bandwidth	LM7171A			125		MHz
		LM7171B			125		
	−3dB frequency	A_V = +2	LM7171A		140		MHz
			LM7171B		140		
φ_m	Phase margin	LM7171A			68		Deg
		LM7171B			57		
t_s	Settling time (0.1%)	A_V = −1, V_{OUT} = ±1V, R_L = 500Ω	LM7171A		15		ns
			LM7171B		56		
t_p	Propagation delay	A_V = −2, V_{IN} = ±1V, R_L = 500Ω	LM7171A		2.5		ns
			LM7171B		6		
HD2	Second harmonic distortion	LM7171A	f_{IN} = 10kHz		–125		dBc
			f_{IN} = 5MHz		–72		
		LM7171B	f_{IN} = 10kHz		–102		
			f_{IN} = 5MHz		–70		
HD3	Third harmonic distortion	LM7171A	f_{IN} = 10kHz		–129		dBc
			f_{IN} = 5MHz		–81		
		LM7171B	f_{IN} = 10kHz		–110		
			f_{IN} = 5MHz		–51		
e_n	Input-referred voltage noise	f = 10kHz	LM7171A		8.5		nV/√Hz
			LM7171B		14		
i_n	Input-referred current noise	f = 10kHz	LM7171A		1		pA/√Hz
			LM7171B		1.8		

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5.7 Typical Characteristics: LM7171A

at T_A= 25°C (unless otherwise noted)

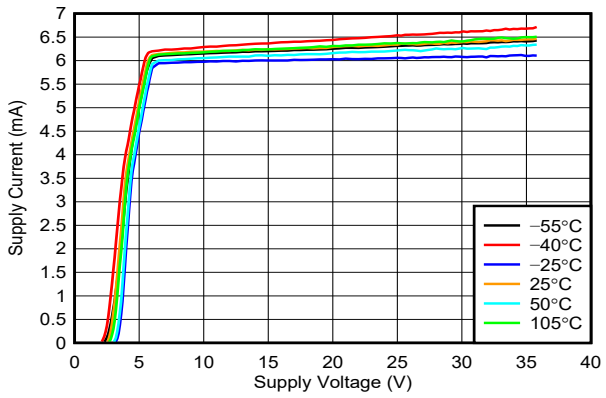

Figure 5-1. Supply Current vs Supply Voltage

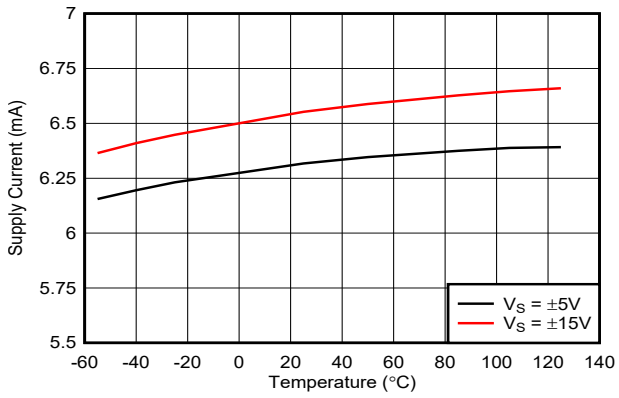

Figure 5-2. Supply Current vs Temperature

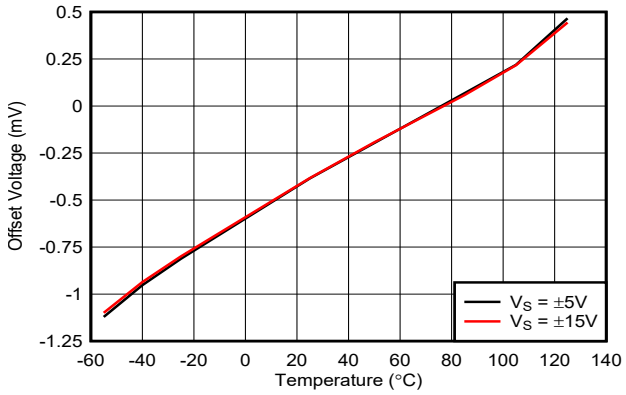

Figure 5-3. Input Offset Voltage vs Temperature

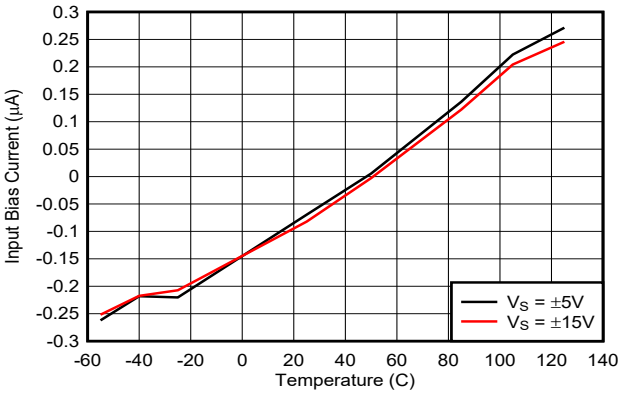

Figure 5-4. Input Bias Current vs Temperature

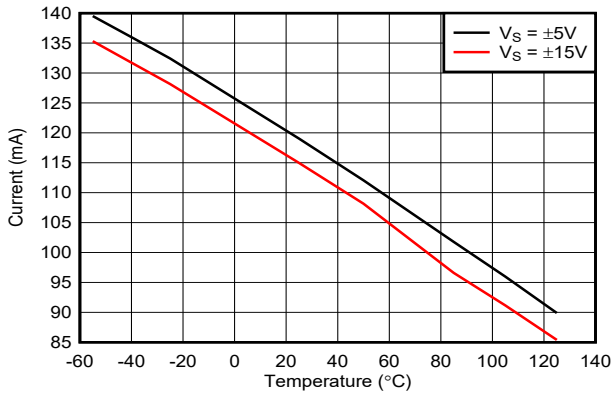

Figure 5-5. Short Circuit Current vs Temperature (Sourcing)

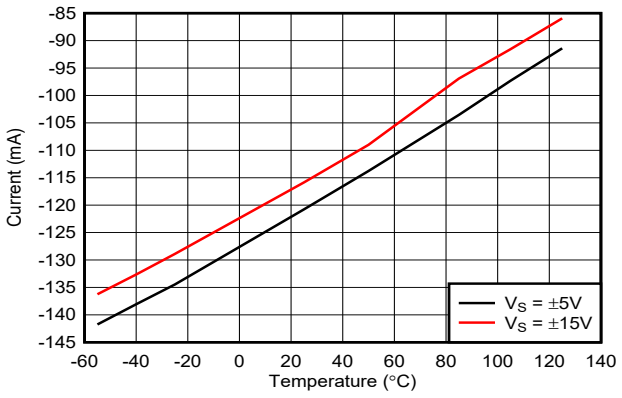

Figure 5-6. Short Circuit Current vs Temperature (Sinking)

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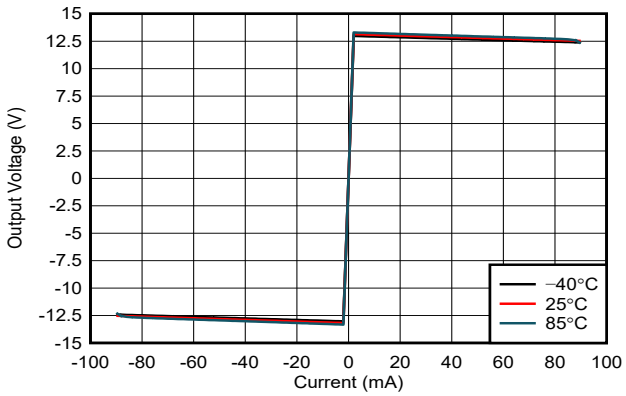
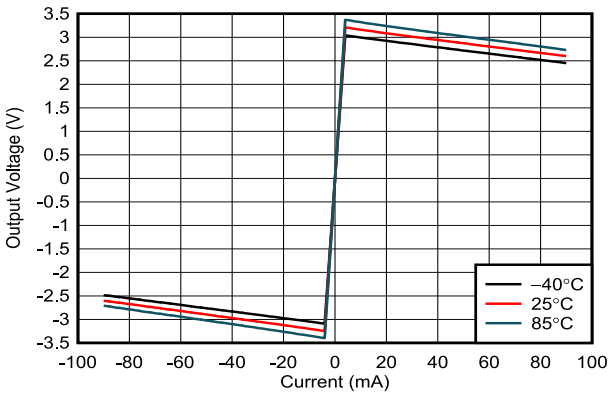
5.7 Typical Characteristics: LM7171A (continued)

at T_A= 25°C (unless otherwise noted)



V_S = ±15V

Figure 5-7. Output Voltage vs Output Current



V_S = ±5V

Figure 5-8. Output Voltage vs Output Current

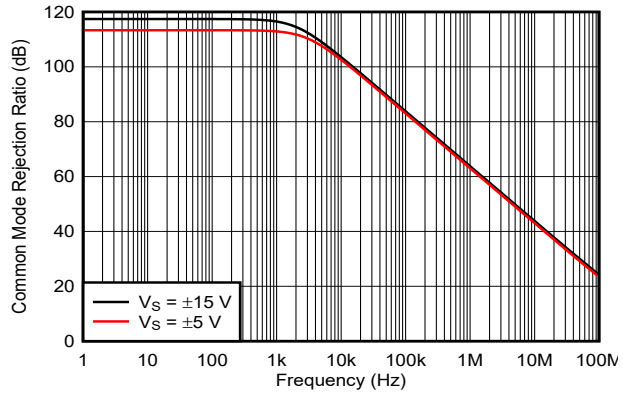
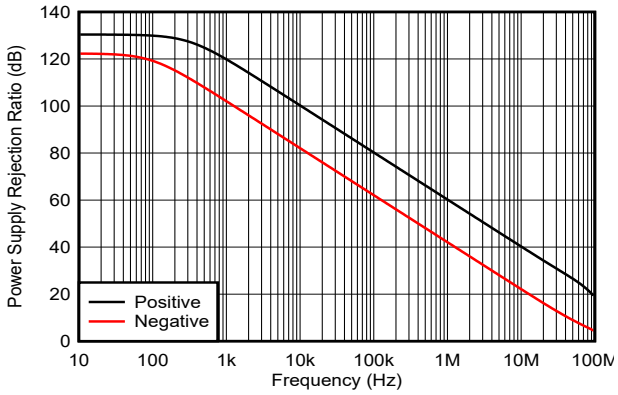
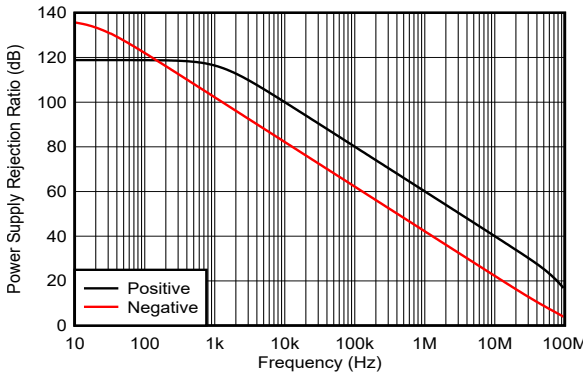


Figure 5-9. CMRR vs Frequency



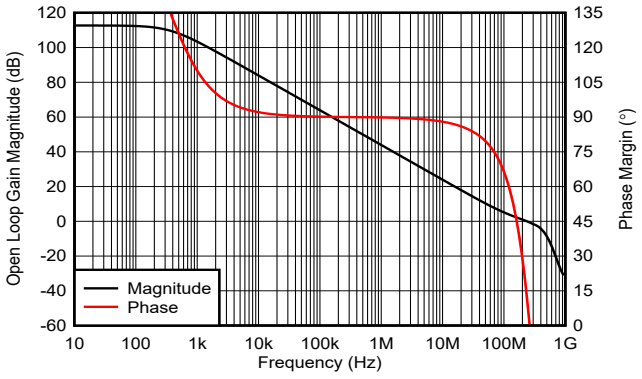
V_S = 30V

Figure 5-10. PSRR vs Frequency



V_S = 10V

Figure 5-11. PSRR vs Frequency

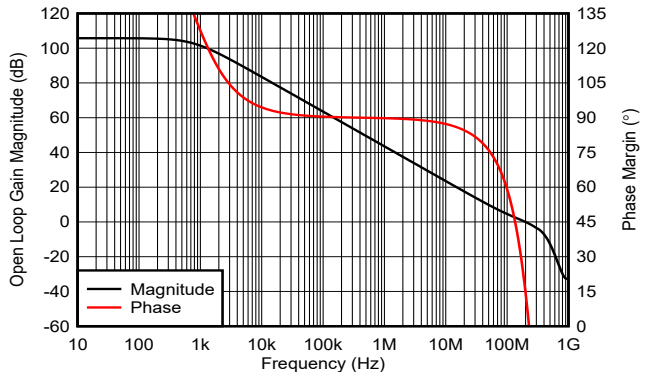


V_S = ±15V

Figure 5-12. Open Loop Frequency Response

5.7 Typical Characteristics: LM7171A (continued)

at T_A= 25°C (unless otherwise noted)



V_S = ±5V

Figure 5-13. Open Loop Frequency Response

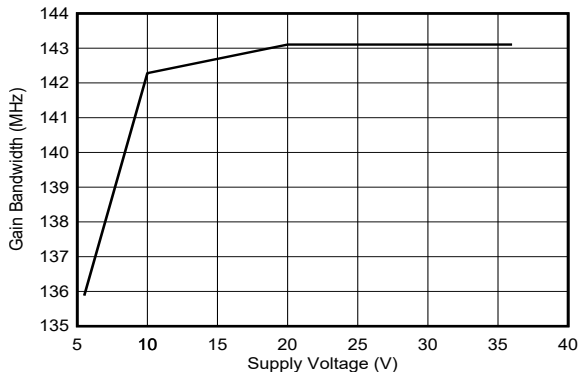


Figure 5-14. Gain-Bandwidth Product vs Supply Voltage

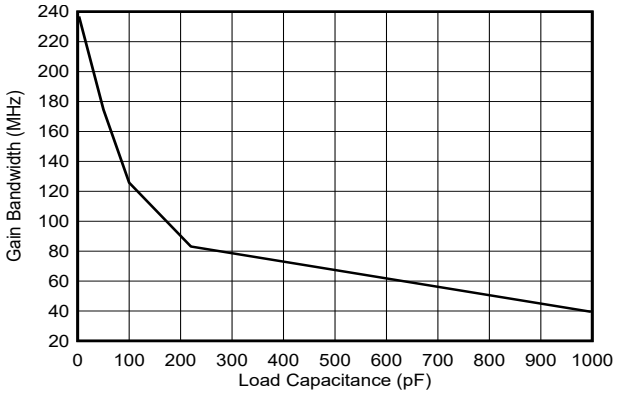


Figure 5-15. Gain-Bandwidth Product vs Load Capacitance

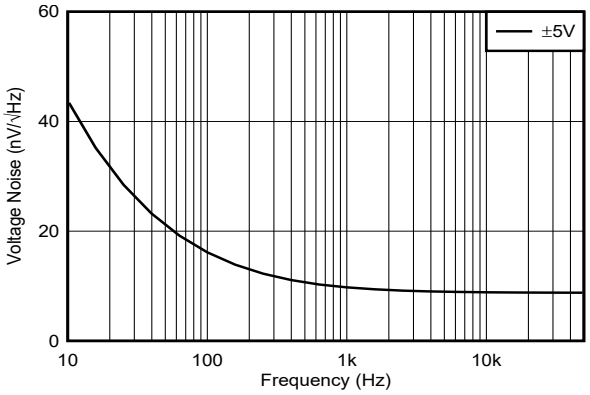


Figure 5-16. Input Voltage Noise vs Frequency

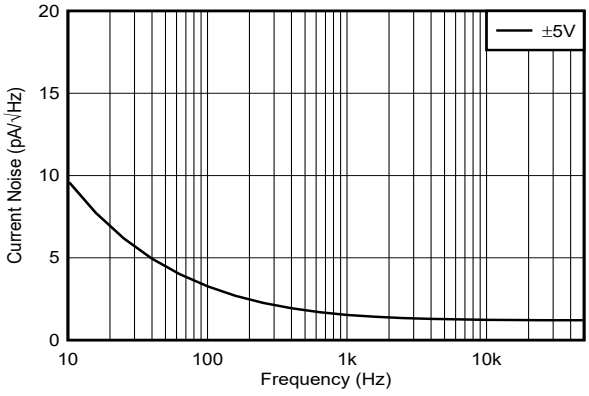


Figure 5-17. Input Current Noise vs Frequency

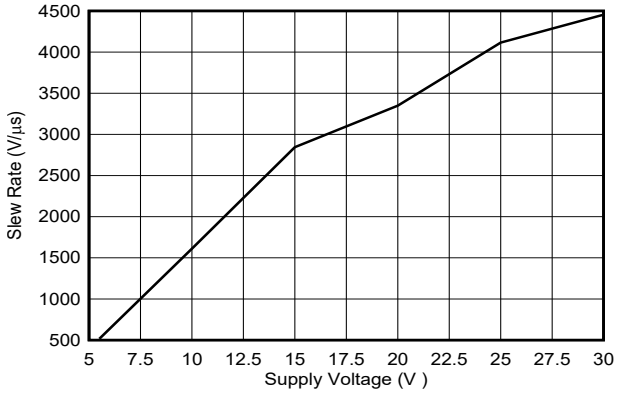


Figure 5-18. Slew Rate vs Supply Voltage

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5.7 Typical Characteristics: LM7171A (continued)

at T_A= 25°C (unless otherwise noted)

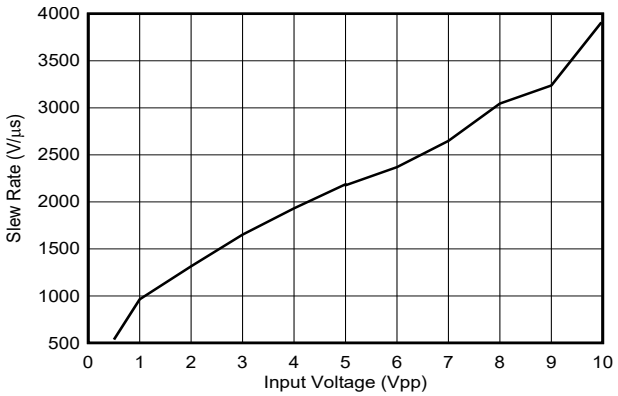


Figure 5-19. Slew Rate vs Input Voltage

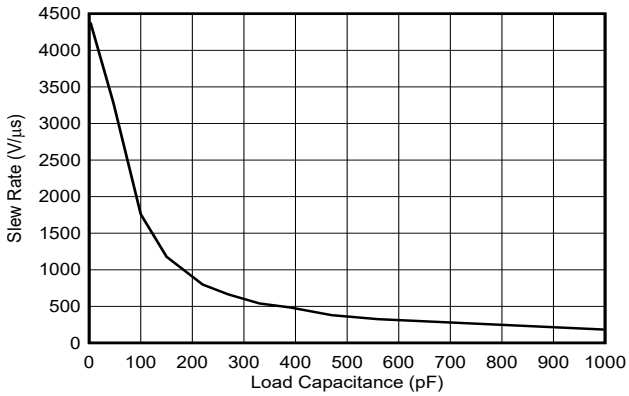
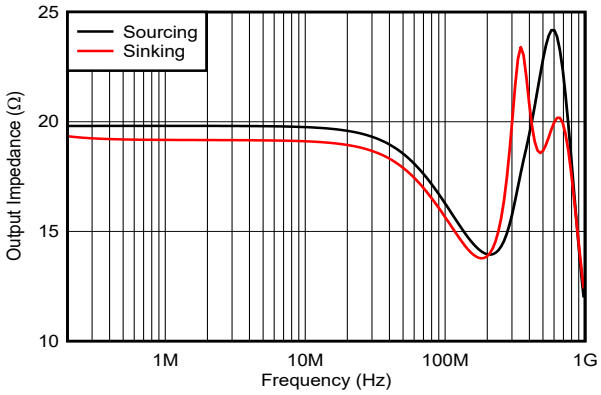
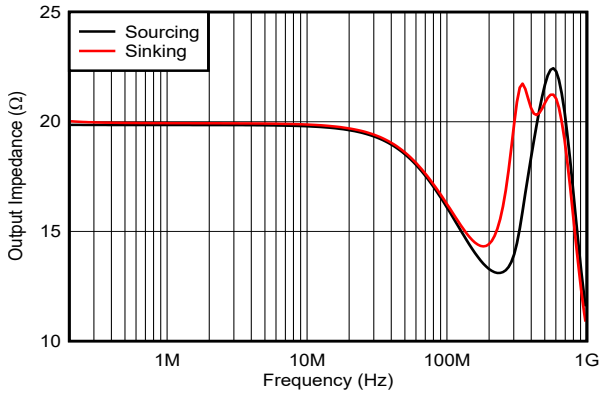


Figure 5-20. Slew Rate vs Load Capacitance



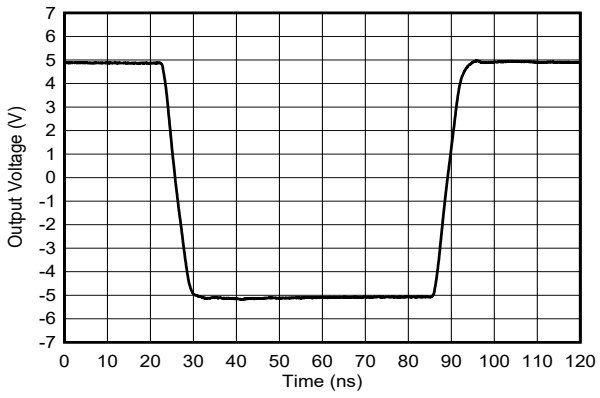
V_S = ±15V

Figure 5-21. Open Loop Output Impedance vs Frequency



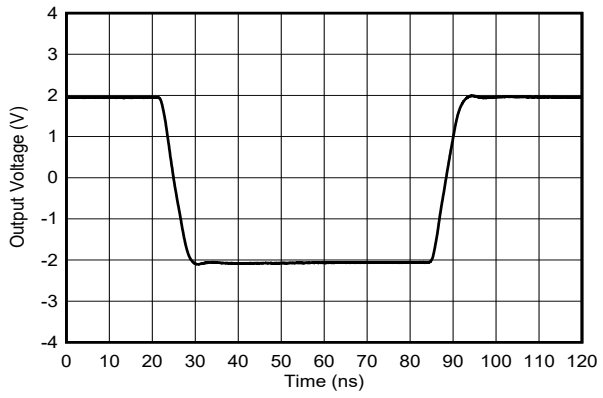
V_S = ±5V

Figure 5-22. Open Loop Output Impedance vs Frequency



A_V = −1 V_S = ±15V

Figure 5-23. Large-Signal Pulse Response



A_V = −1 V_S = ±5V

Figure 5-24. Large-Signal Pulse Response

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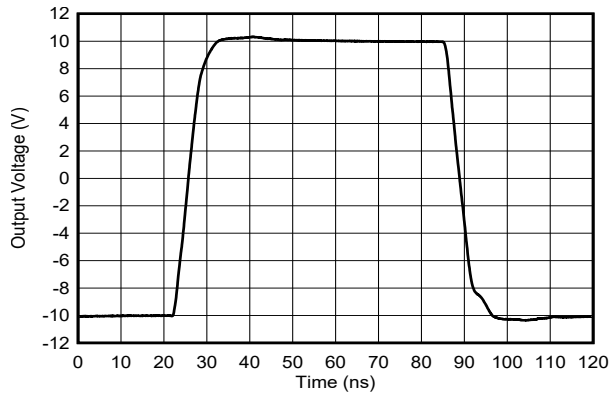
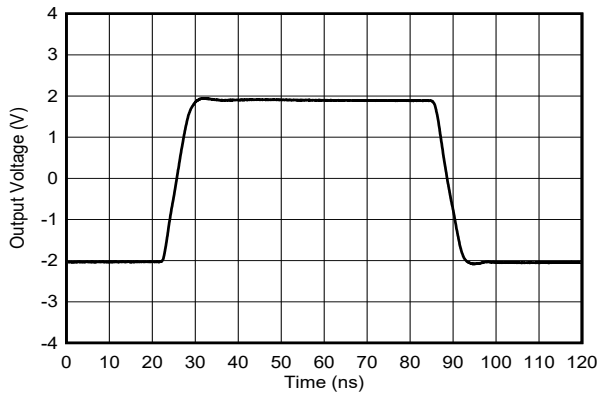
5.7 Typical Characteristics: LM7171A (continued)

at T_A= 25°C (unless otherwise noted)



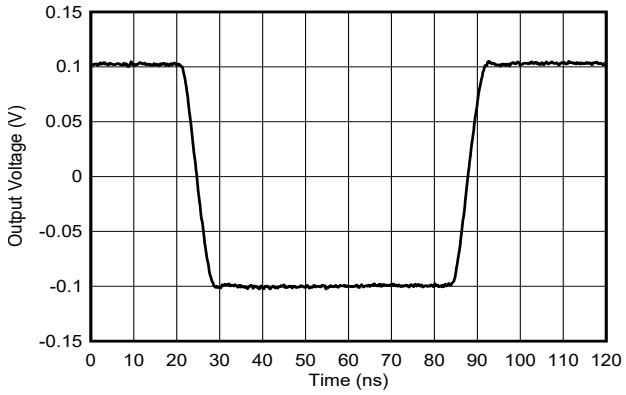
A_V = +2 V_S = ±15V

Figure 5-25. Large-Signal Pulse Response



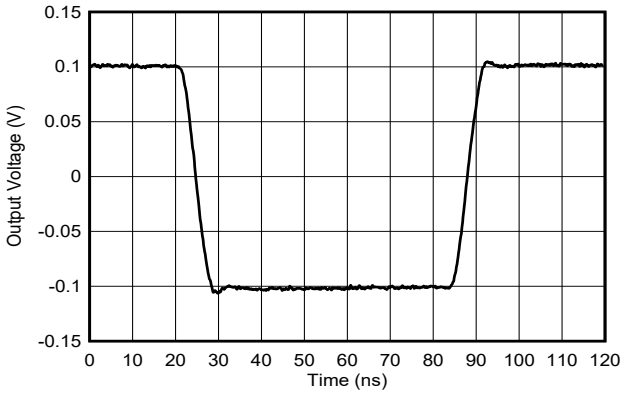
A_V = +2 V_S = ±5V

Figure 5-26. Large-Signal Pulse Response



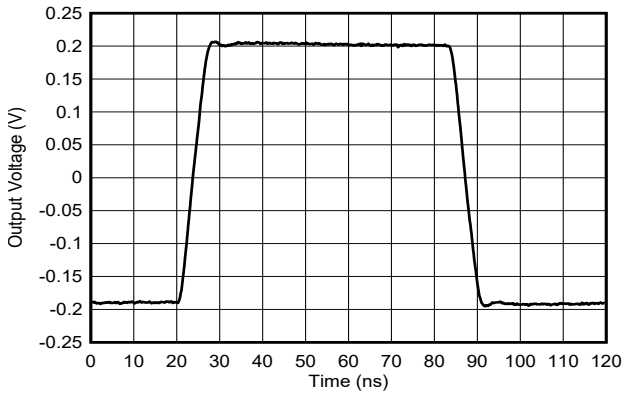
A_V = −1 V_S = ±15V

Figure 5-27. Small-Signal Pulse Response



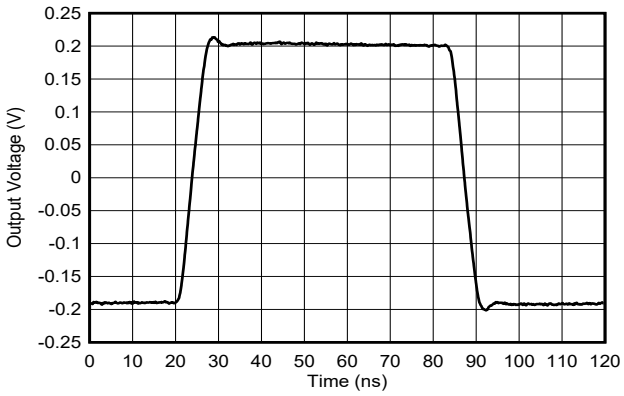
A_V = −1 V_S = ±5V

Figure 5-28. Small-Signal Pulse Response



A_V = +2 V_S = ±15V

Figure 5-29. Small-Signal Pulse Response



A_V = +2 V_S = ±5V

Figure 5-30. Small-Signal Pulse Response

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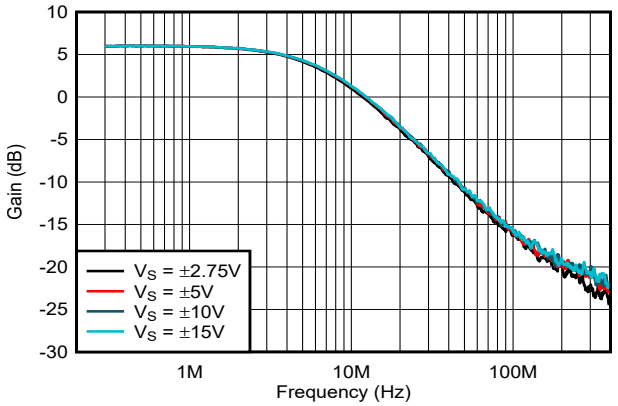
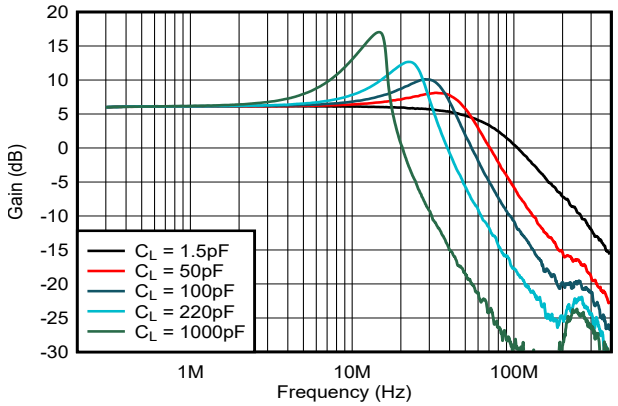
5.7 Typical Characteristics: LM7171A (continued)

at T_A= 25°C (unless otherwise noted)



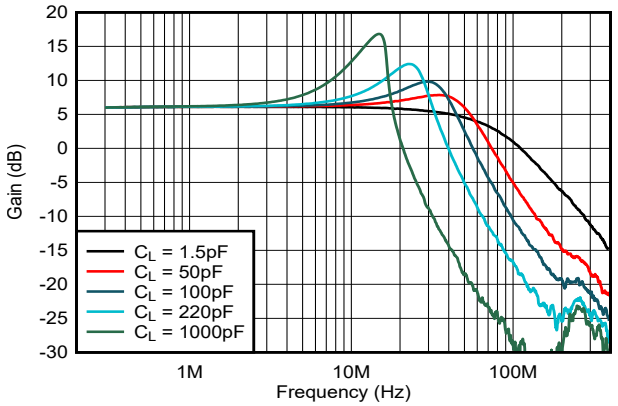
A_V = +2

Figure 5-31. Closed-Loop Frequency Response vs Supply Voltage



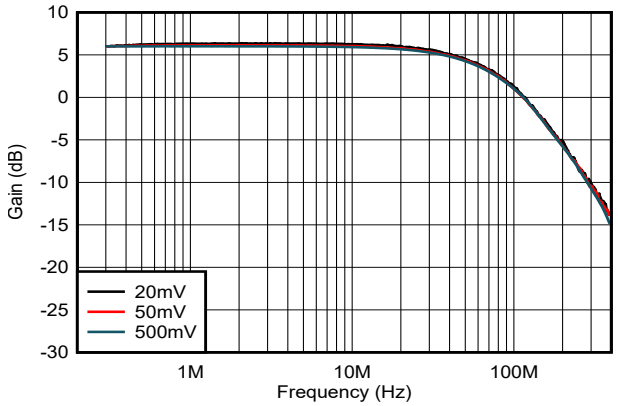
A_V = +2 V_S = ±5V

Figure 5-32. Closed-Loop Frequency Response vs Capacitive Load



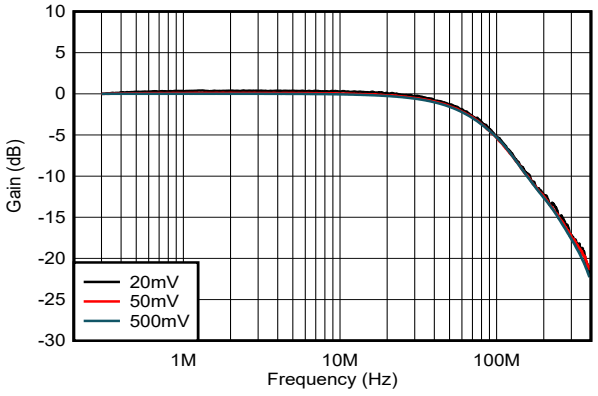
A_V = +2 V_S = ±15V

Figure 5-33. Closed-Loop Frequency Response vs Capacitive Load



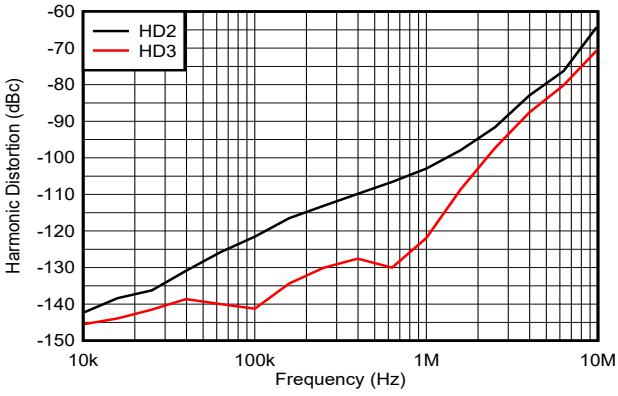
A_V = +2

Figure 5-34. Closed-Loop Frequency Response vs Input Signal Level



A_V = +2

Figure 5-35. Closed-Loop Frequency Response vs Input Signal Level



V_S = ±15V R_L = 100Ω

Figure 5-36. Total Harmonic Distortion vs Frequency

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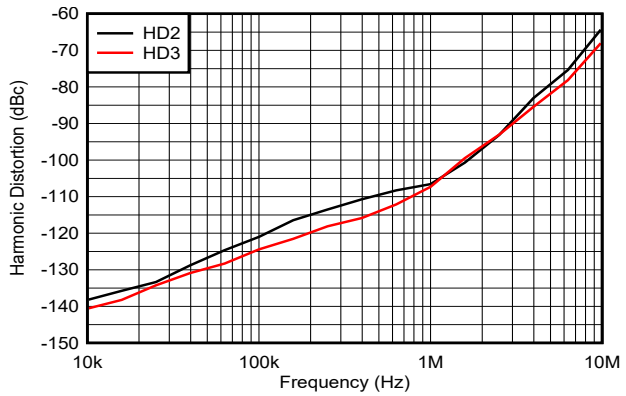
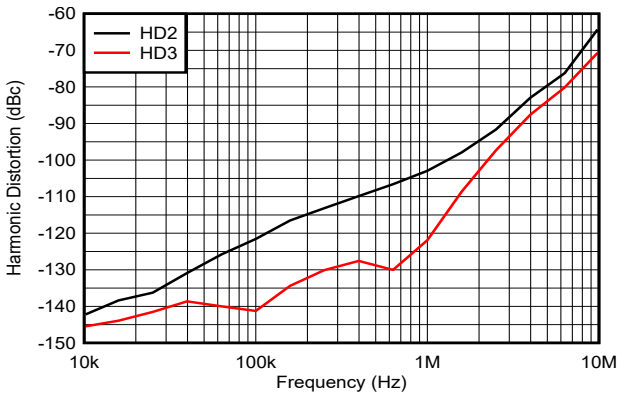
5.7 Typical Characteristics: LM7171A (continued)

at T_A= 25°C (unless otherwise noted)



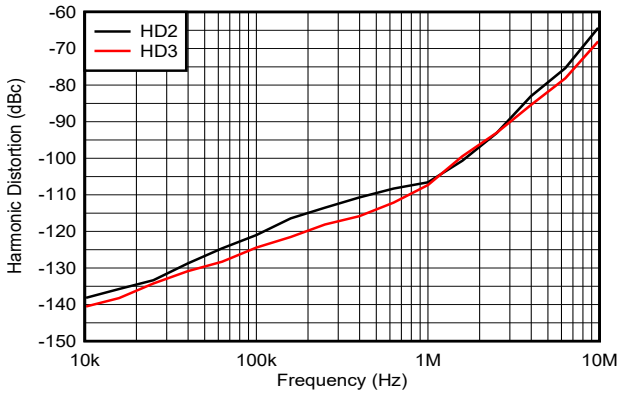
V_S = ±5V R_L = 100Ω

Figure 5-37. Total Harmonic Distortion vs Frequency



V_S = ±15V R_L = 2.5kΩ

Figure 5-38. Harmonic Distortion vs Frequency



V_S = ±5V R_L = 2.5kΩ

Figure 5-39. Harmonic Distortion vs Frequency

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5.8 Typical Characteristics: LM7171B

at T_A= 25°C (unless otherwise noted)

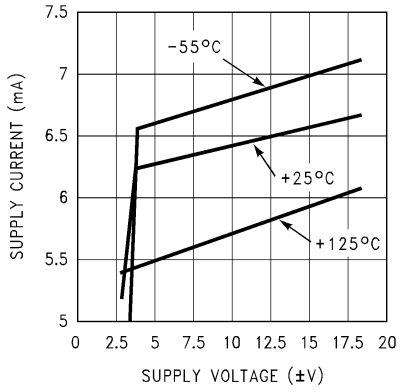

Figure 5-40. Supply Current vs Supply Voltage

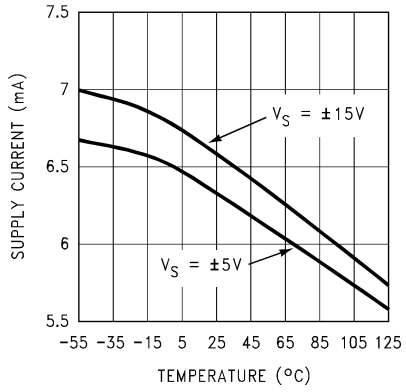

Figure 5-41. Supply Current vs Temperature

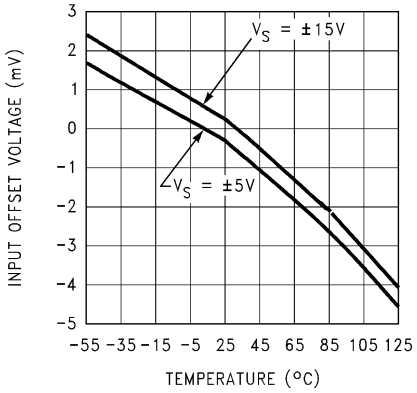

Figure 5-42. Input Offset Voltage vs Temperature

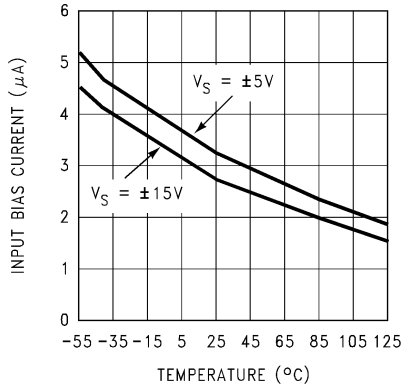

Figure 5-43. Input Bias Current vs Temperature

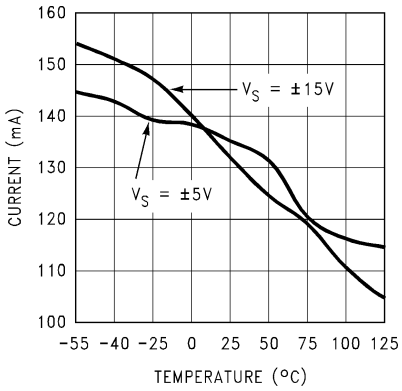

Figure 5-44. Short Circuit Current vs Temperature (Sourcing)

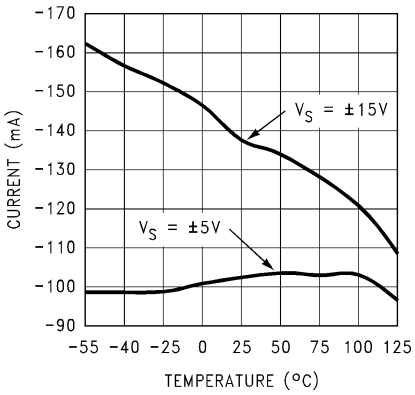

Figure 5-45. Short Circuit Current vs Temperature (Sinking)

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5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)

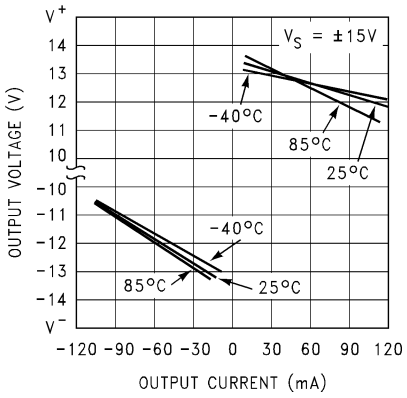

Figure 5-46. Output Voltage vs Output Current

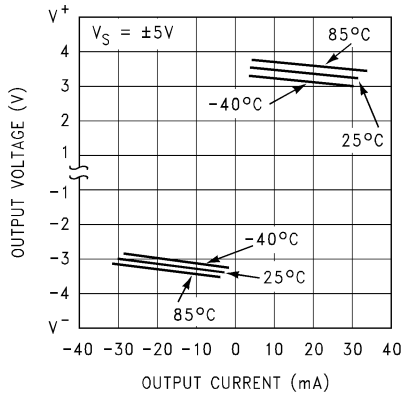

Figure 5-47. Output Voltage vs Output Current

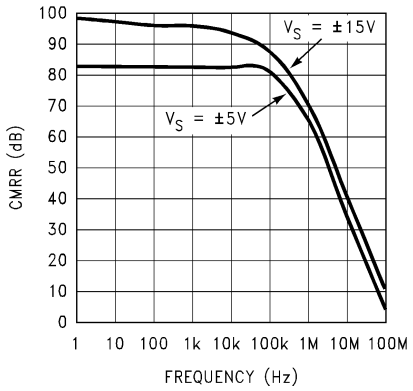

Figure 5-48. CMRR vs Frequency

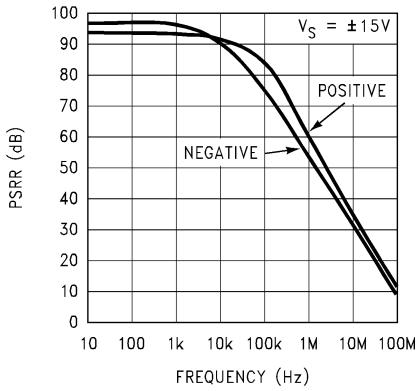

Figure 5-49. PSRR vs Frequency

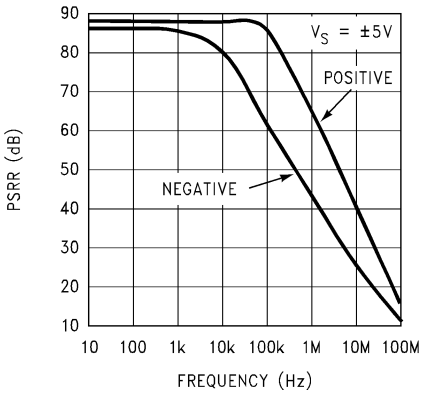

Figure 5-50. PSRR vs Frequency

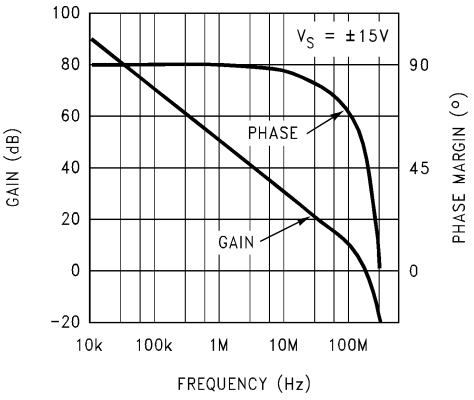

Figure 5-51. Open Loop Frequency Response

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5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)

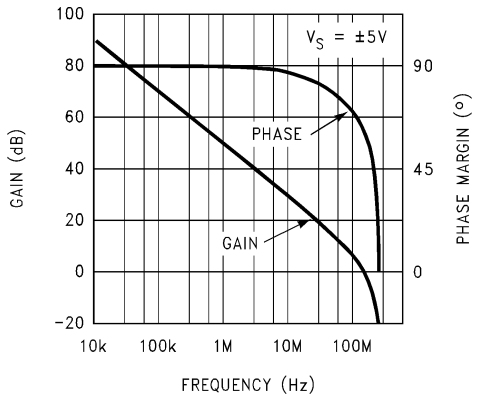

Figure 5-52. Open Loop Frequency Response

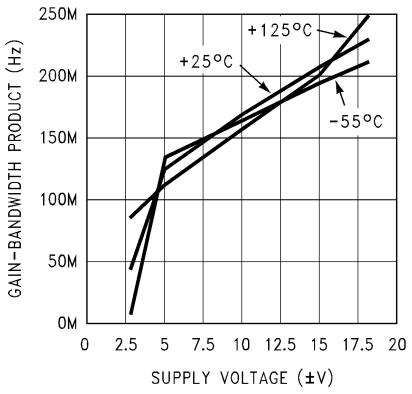

Figure 5-53. Gain-Bandwidth Product vs Supply Voltage

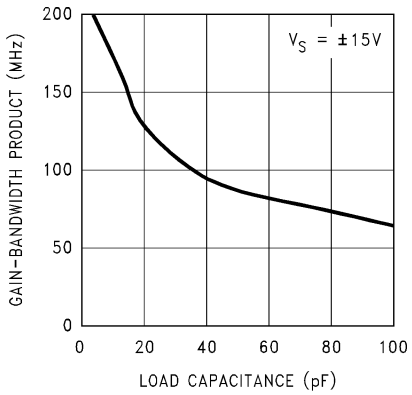

Figure 5-54. Gain-Bandwidth Product vs Load Capacitance

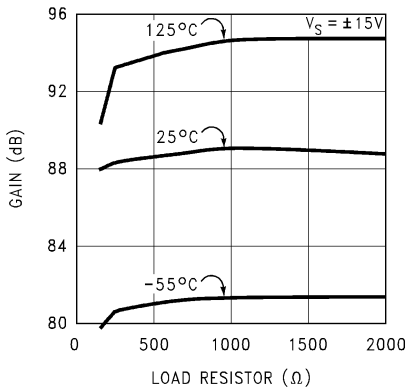

Figure 5-55. Large Signal Voltage Gain vs Load

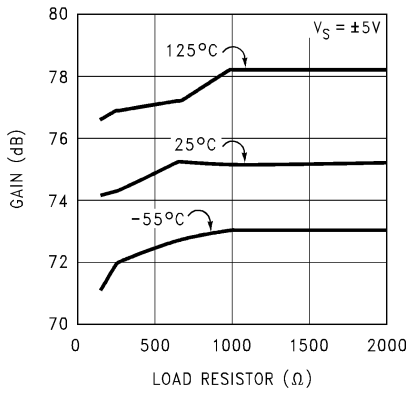

Figure 5-56. Large Signal Voltage Gain vs Load

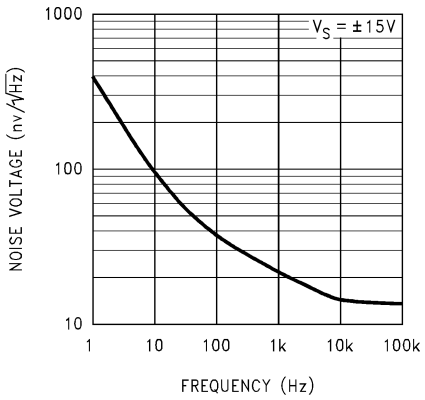

Figure 5-57. Input Voltage Noise vs Frequency

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5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)

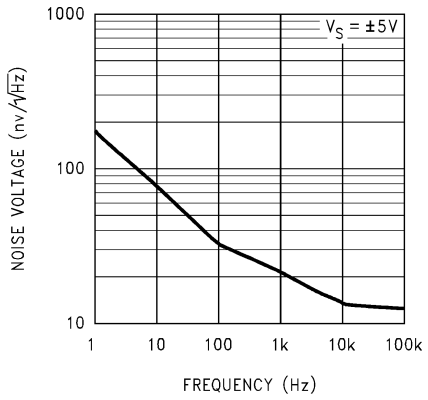

Figure 5-58. Input Voltage Noise vs Frequency

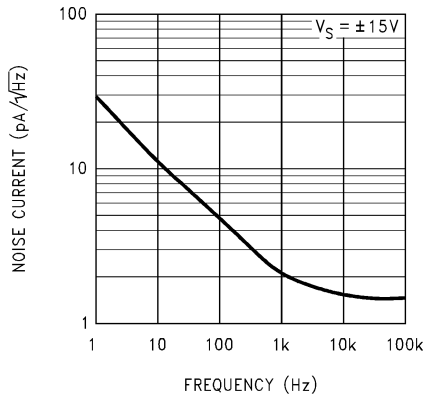

Figure 5-59. Input Current Noise vs Frequency

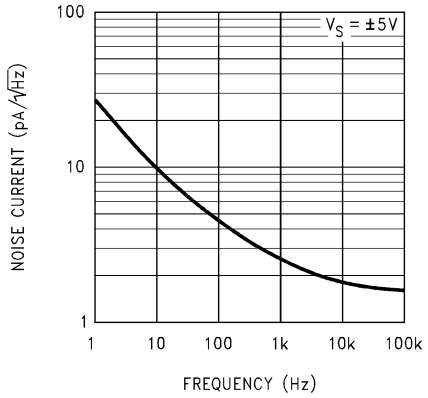

Figure 5-60. Input Current Noise vs Frequency

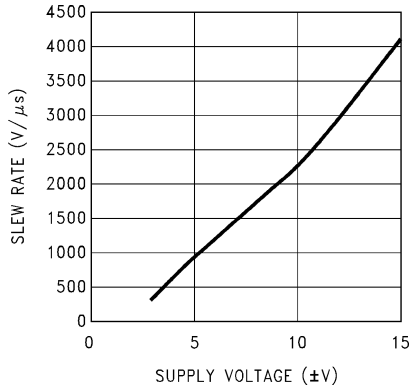

Figure 5-61. Slew Rate vs Supply Voltage

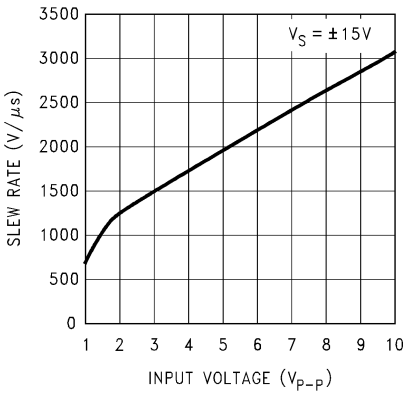

Figure 5-62. Slew Rate vs Input Voltage

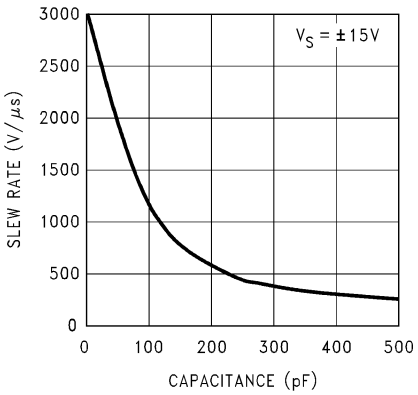

Figure 5-63. Slew Rate vs Load Capacitance

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5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)

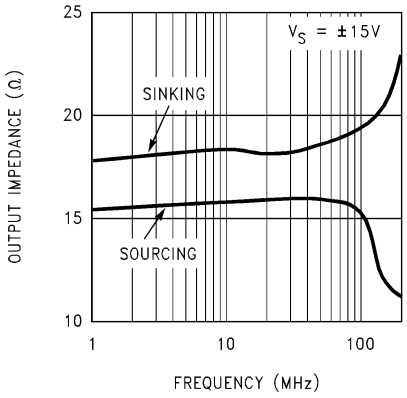


Figure 5-64. Open Loop Output Impedance vs Frequency

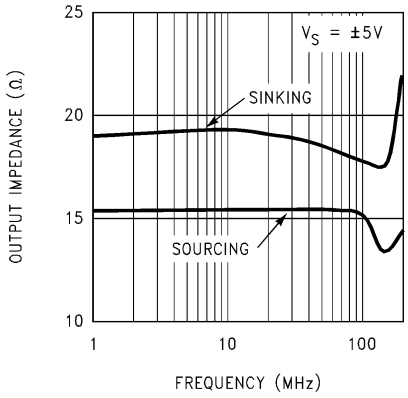
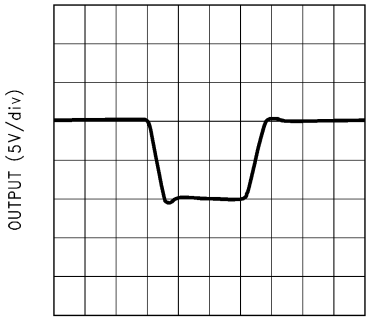
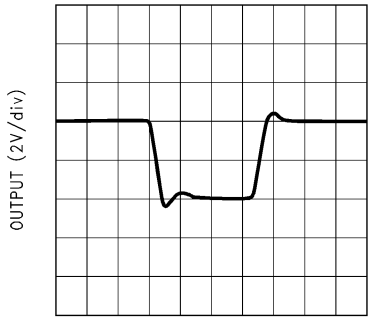


Figure 5-65. Open Loop Output Impedance vs Frequency



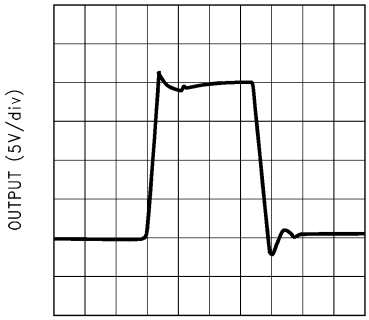
A_V = –1 V_S = ±15V

Figure 5-66. Large-Signal Pulse Response



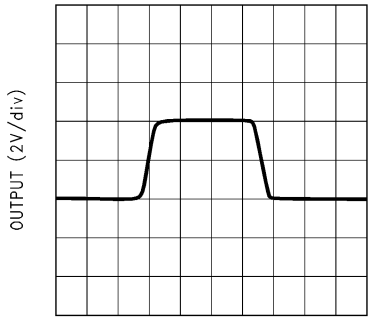
A_V = –1 V_S = ±5V

Figure 5-67. Large-Signal Pulse Response



A_V = +2 V_S = ±15V

Figure 5-68. Large-Signal Pulse Response



A_V = +2 V_S = ±5V

Figure 5-69. Large-Signal Pulse Response

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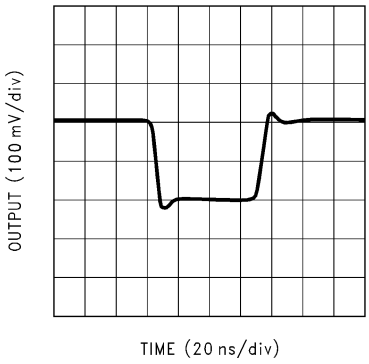
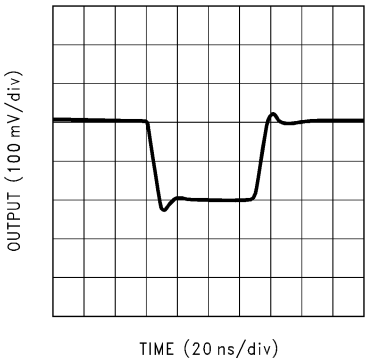
5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)



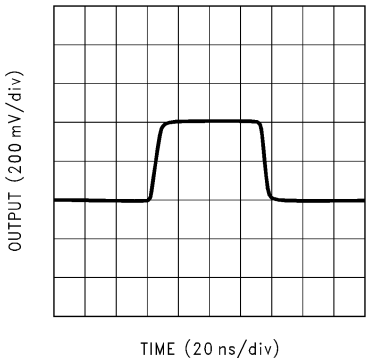
A_V = –1 V_S = ±15V

Figure 5-70. Small-Signal Pulse Response



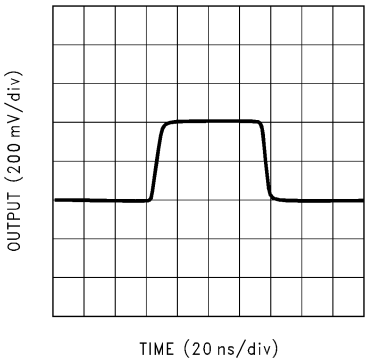
A_V = –1 V_S = ±5V

Figure 5-71. Small-Signal Pulse Response



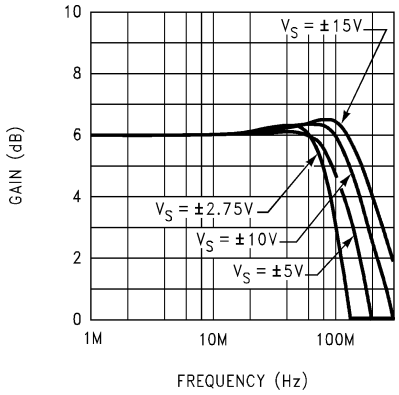
A_V = +2 V_S = ±15V

Figure 5-72. Small-Signal Pulse Response



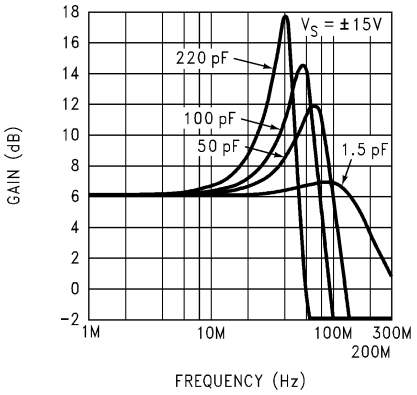
A_V = +2 V_S = ±5V

Figure 5-73. Small-Signal Pulse Response



A_V = +2

Figure 5-74. Closed-Loop Frequency Response vs Supply Voltage



A_V = +2

Figure 5-75. Closed-Loop Frequency Response vs Capacitive Load

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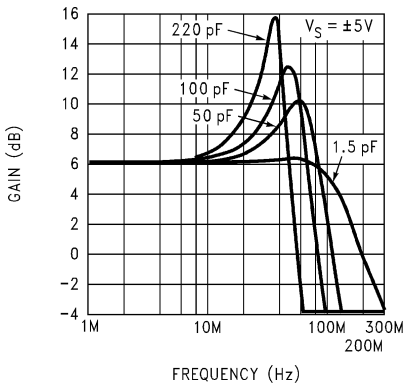
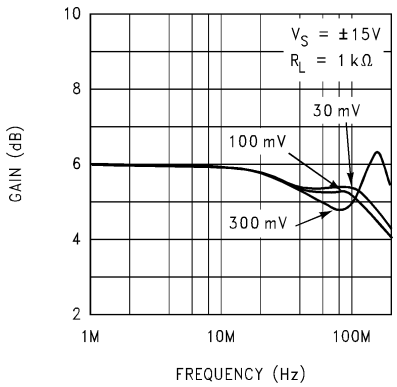
5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)



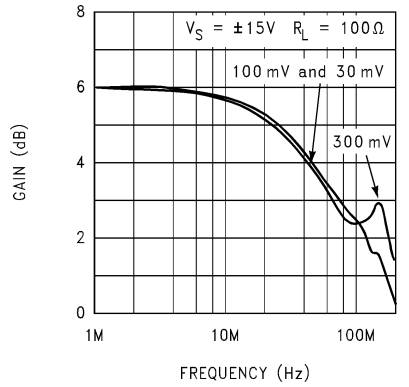
A_V = +2

Figure 5-76. Closed-Loop Frequency Response vs Capacitive Load



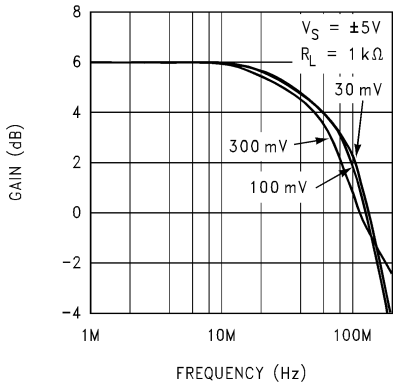
A_V = +2

Figure 5-77. Closed-Loop Frequency Response vs Input Signal Level



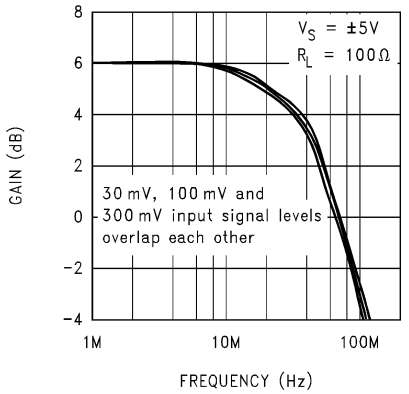
A_V = +2

Figure 5-78. Closed-Loop Frequency Response vs Input Signal Level



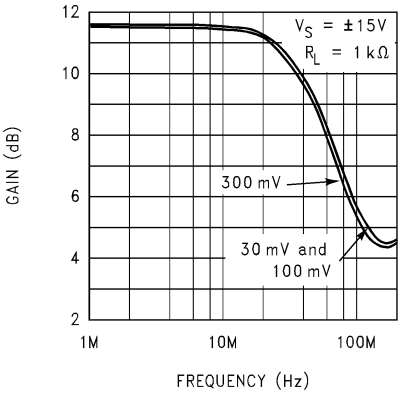
A_V = +2

Figure 5-79. Closed-Loop Frequency Response vs Input Signal Level



A_V = +2

Figure 5-80. Closed-Loop Frequency Response vs Input Signal Level



A_V = +4

Figure 5-81. Closed-Loop Frequency Response vs Input Signal Level

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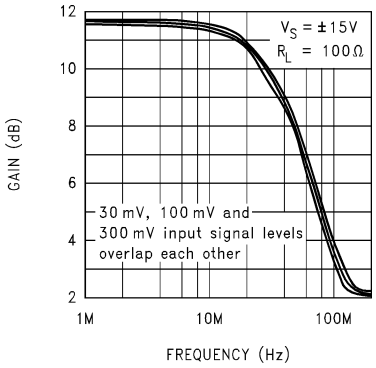
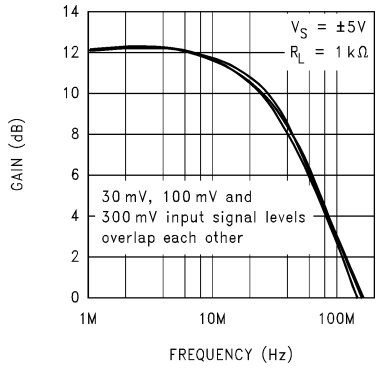
5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)



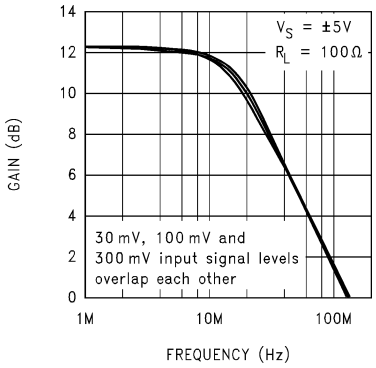
A_V = +4

Figure 5-82. Closed-Loop Frequency Response vs Input Signal Level



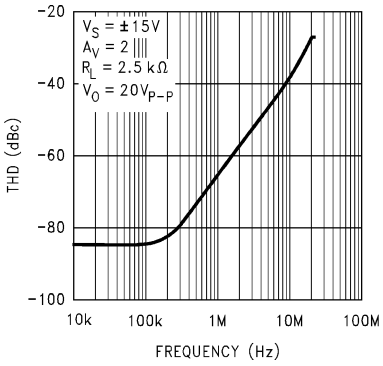
A_V = +4

Figure 5-83. Closed-Loop Frequency Response vs Input Signal Level



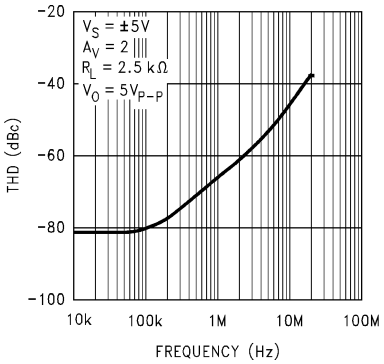
A_V = +4

Figure 5-84. Closed-Loop Frequency Response vs Input Signal Level



THD measurement at low frequency limited by test instrument

Figure 5-85. Total Harmonic Distortion vs Frequency



THD measurement at low frequency limited by test instrument

Figure 5-86. Total Harmonic Distortion vs Frequency

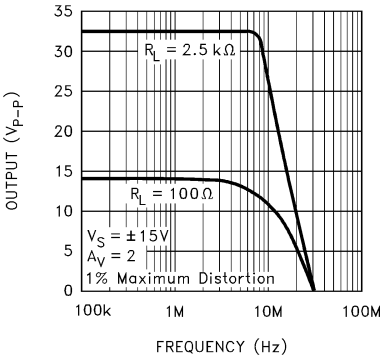


Figure 5-87. Undistorted Output Swing vs Frequency

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5.8 Typical Characteristics: LM7171B (continued)

at T_A= 25°C (unless otherwise noted)

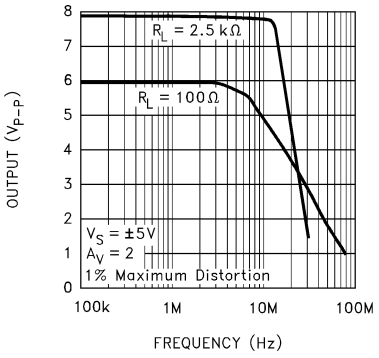


Figure 5-88. Undistorted Output Swing vs Frequency

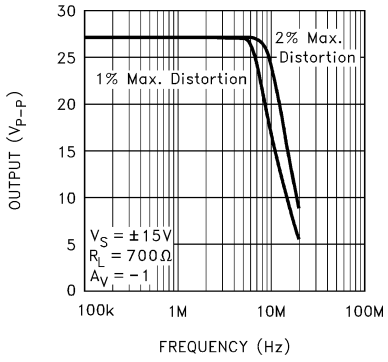
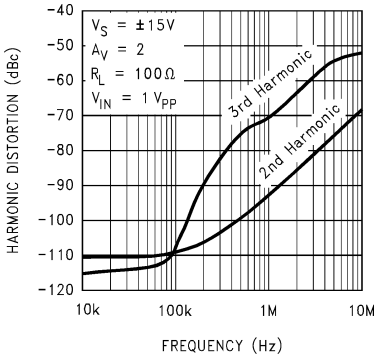
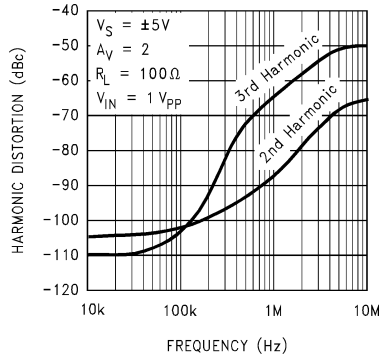


Figure 5-89. Undistorted Output Swing vs Frequency



THD measurement at low frequency limited by test instrument

Figure 5-90. Harmonic Distortion vs Frequency



THD measurement at low frequency limited by test instrument

Figure 5-91. Harmonic Distortion vs Frequency

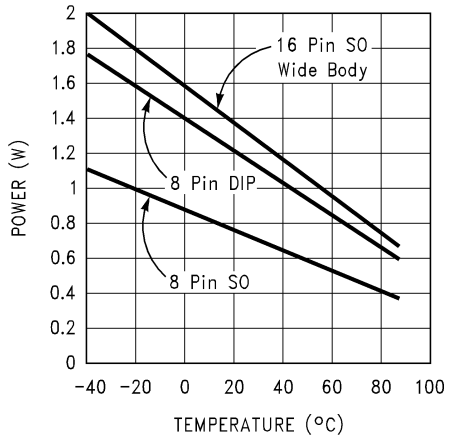


Figure 5-92. Maximum Power Dissipation vs Ambient Temperature

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6 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

6.1 Application Information

The LM7171 is a very high-speed, voltage-feedback amplifier (VFA). This device consumes only 6.5mA of supply current while providing a unity-gain bandwidth of 200MHz and a slew rate of 4100V/µs. The LM7171 also has other great features such as low differential gain and phase and high output current.

The LM7171 is a true VFA. Unlike a current-feedback amplifier (CFA) with a low inverting input impedance and a high noninverting input impedance, both inputs of a VFA have high-impedance nodes. The low-impedance inverting input of a CFA and a feedback capacitor create an additional pole that leads to instability. As a result, CFAs cannot be used in traditional op-amp circuits such as photodiode amplifiers, I-to-V converters, and integrators, where a feedback capacitor is required.

6.1.1 Circuit Operation

The class AB input stage in LM7171 is fully symmetrical and has a similar slewing characteristic to a CFA. In the LM7171 simplified schematic, Q1 through Q4 form the equivalent of the current-feedback input buffer, R_E the equivalent of the feedback resistor, and stage A buffers the inverting input. The triple-buffered output stage isolates the gain stage from the load to provide low output impedance.

6.1.2 Slew Rate Characteristic

The slew rate of LM7171 is determined by the current available to charge and discharge an internal high impedance node capacitor. This current is the differential input voltage divided by the total degeneration resistor R_E. Therefore, the slew rate is proportional to the input voltage level, and the higher slew rates are achievable in the lower gain configurations. A curve of slew rate versus input voltage level is provided in *Section 5.8*.

When a very fast large signal pulse is applied to the input of an amplifier, some overshoot or undershoot occurs. By placing an external resistor such as 1kΩ in series with the input of LM7171, the bandwidth is reduced to help lower the overshoot.

6.1.2.1 Slew-Rate Limitation

If the amplifier input signal amplitude is too large and the frequency too high, the amplifier is slew-rate limited. This limiting can cause ringing in the time domain and peaking in the frequency domain at the output of the amplifier.

For the A_V = +2 curves, slight peaking occurs. This peaking at high frequency (> 100MHz) is due to a large input signal at a high enough frequency that exceeds the amplifier slew rate. The peaking in the frequency response does not limit the pulse response in the time domain, and the LM7171 is stable with a noise gain of ≥ +2.

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6.1.3 Compensation for Input Capacitance

The combination of an amplifier input capacitance with the gain setting resistors adds a pole that can cause peaking or oscillation. To solve this problem, a feedback capacitor with a value of

$$C_F > (R_G \times C_{IN}) / R_F \quad (1)$$

can be used to cancel that pole. For LM7171, a feedback capacitor of 2pF is recommended. Figure 6-1 illustrates the compensation circuit.

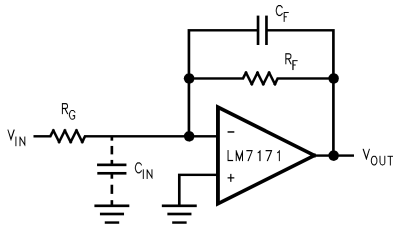

Figure 6-1. Compensating for Input Capacitance

6.2 Typical Applications

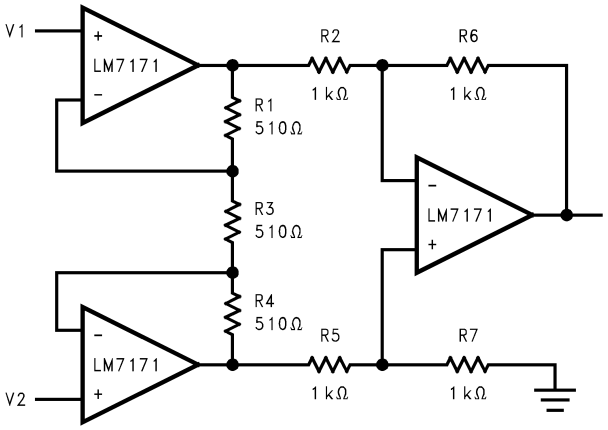

Figure 6-2. Fast Instrumentation Amplifier

$$V_{IN} = V_2 - V_1$$

if R6 = R2, R7 = R5, and R1 = R4

$$\frac{V_{OUT}}{V_{IN}} = \frac{R6}{R2}\left(1 + 2\frac{R1}{R3}\right) = 3$$

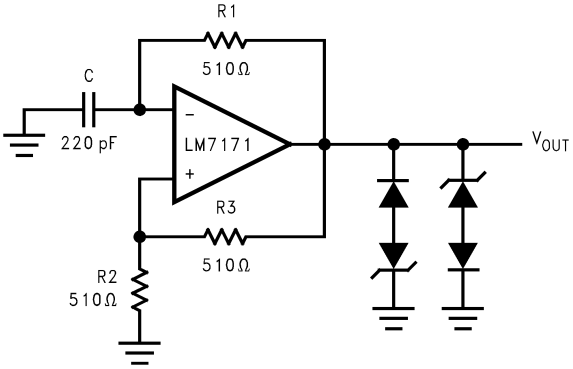

Figure 6-3. Multivibrator

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$$f = \frac{1}{2\left(R1\,C\ln\left(1 + 2\frac{R2}{R3}\right)\right)}$$

f = 4 MHz

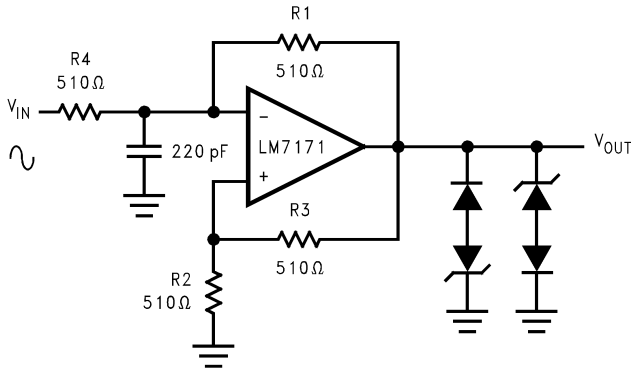

Figure 6-4. Pulse Width Modulator

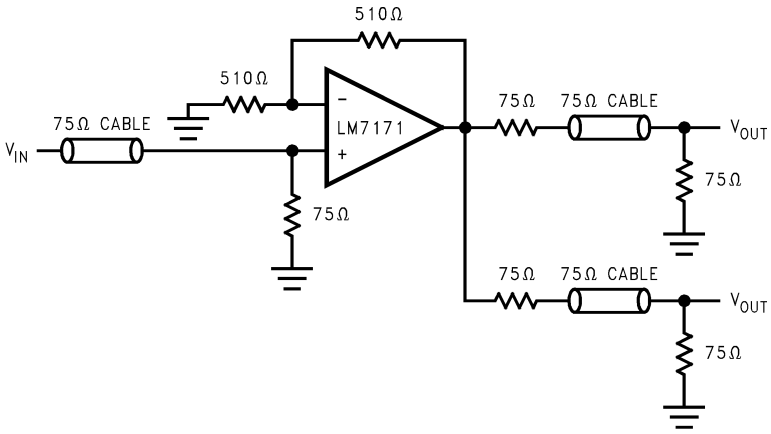

Figure 6-5. Video Line Driver

6.3 Power Supply Recommendations

6.3.1 Power-Supply Bypassing

Bypassing the power supply is necessary to maintain low power-supply impedance across frequency. To bypass both positive and negative power supplies individually, place 0.01µF ceramic capacitors directly to the power-supply pins, and 2.2µF tantalum capacitors close to the power-supply pins.

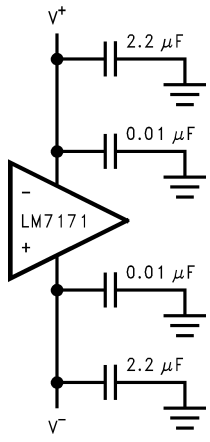

Figure 6-6. Power-Supply Bypassing

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6.3.2 Termination

In high-frequency applications, reflections occur if signals are not properly terminated. Figure 6-7 shows a properly terminated signal while Figure 6-8 shows an improperly terminated signal.

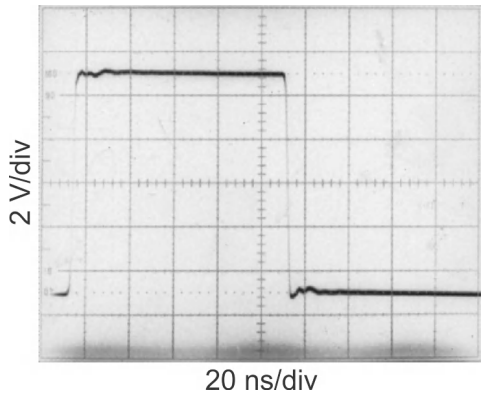

Figure 6-7. Properly Terminated Signal

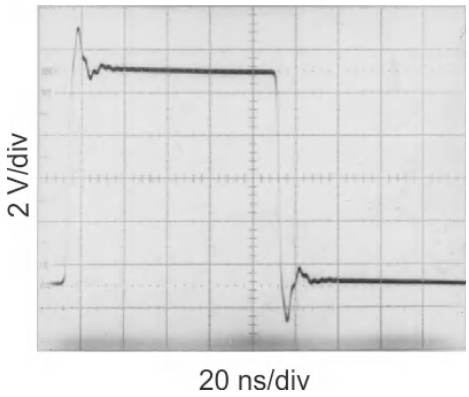

Figure 6-8. Improperly Terminated Signal

To minimize reflection, use coaxial cable with matching characteristic impedance to the signal source. Terminate the other end of the cable with the same-value terminator or resistor. For commonly used cables, RG59 has a 75Ω characteristic impedance, and RG58 has a 50Ω characteristic impedance.

6.3.3 Driving Capacitive Loads

Amplifiers driving capacitive loads can oscillate or have ringing at the output. To eliminate oscillation or reduce ringing, place an isolation resistor as shown in Figure 6-9. The combination of the isolation resistor and the load capacitor forms a pole to increase stability by adding more phase margin to the overall system. The desired performance depends on the value of the isolation resistor; the bigger the isolation resistor, the more damped the pulse response becomes. For LM7171, a 50Ω isolation resistor is recommended for initial evaluation. Figure 6-10 shows the LM7171 driving a 150pF load with the 50Ω isolation resistor.

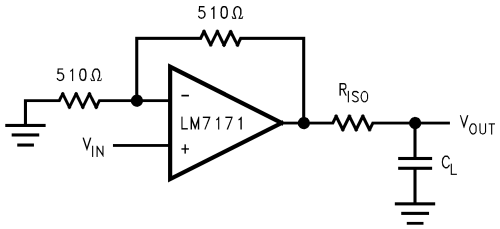

Figure 6-9. Isolation Resistor Used to Drive Capacitive Load

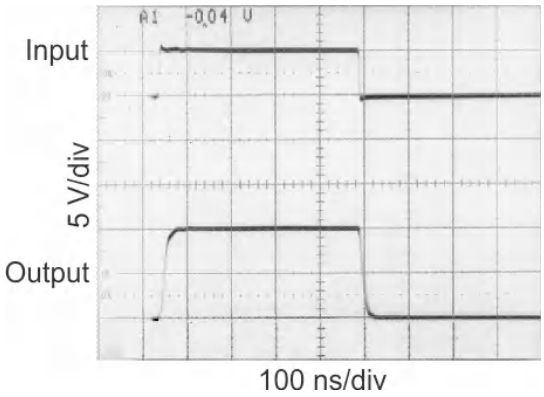

Figure 6-10. The LM7171 Driving a 150pF Load With a 50Ω Isolation Resistor

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6.3.4 Power Dissipation

The maximum power allowed to dissipate in a device is defined as:

$$P_D = (T_{J(MAX)} - T_A) / \theta_{JA} \quad (2)$$

where

- P_D is the power dissipation in a device
- $T_{J(max)}$ is the maximum junction temperature
- T_A is the ambient temperature
- $R_{\theta JA}$ is the thermal resistance of a particular package

For example, for the LM7171 in a SOIC-8 package, the maximum power dissipation at 25°C ambient temperature is 730mW.

Thermal resistance, $R_{\theta JA}$, depends on parameters such as die size, package size and package material. The smaller the die size and package, the higher $R_{\theta JA}$ becomes. The 8-pin DIP package has a lower thermal resistance (108°C/W) than that of 8-pin SOIC (172°C/W). Therefore, for higher dissipation capability, use an 8-pin DIP package.

The total power dissipated in a device can be calculated as:

$$P_D = P_Q + P_L \quad (3)$$

where

- P_Q is the quiescent power dissipated in a device with no load connected at the output. P_L is the power dissipated in the device with a load connected at the output; P_L is not the power dissipated by the load.

  Furthermore,
- P_Q is the supply current × total supply voltage with no load
- P_L is the output current × (voltage difference between supply voltage and output voltage of the same side of supply voltage)

For example, the total power dissipated by the LM7171 with V_S = ±15V and output voltage of 10V into 1kΩ is

$$P_D = P_Q + P_L \quad (4)$$

$$= (6.5mA) \times (30V) + (10mA) \times (15V - 10V) \quad (5)$$

$$= 195mW + 50mW \quad (6)$$

$$= 245mW \quad (7)$$

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6.4 Layout

6.4.1 Layout Guidelines

6.4.1.1 Printed Circuit Board and High-Speed Op Amps

There are many things to consider when designing printed circuit boards (PCBs) for high-speed op amps. Without proper caution, excessive ringing, oscillation, and other degraded ac performance can easily occur in high-speed circuits. As a rule, keep signal traces short and wide to provide low inductance and low impedance paths. Ground any unused board space to reduce stray signal pickup. Ground critical components at a common point to eliminate voltage drop. Sockets add capacitance to the board and can affect high-frequency performance. Soldering the amplifier directly into the PCB without using any socket is better.

6.4.1.2 Using Probes

Active (FET) probes are an excellent choice for taking high-frequency measurements because of the wide bandwidth, high input impedance, and low input capacitance. However, the probe ground leads provide a long ground loop that produces errors in measurement. Instead, ground the probes directly by removing the ground leads and probe jackets and using scope probe jacks.

6.4.1.3 Component Selection and Feedback Resistor

In high-speed applications, keep all component leads short. For discrete components, choose carbon composition-type resistors and mica-type capacitors. Surface-mount components are preferred over discrete components for minimum inductive effect.

Large values of feedback resistors can couple with parasitic capacitance and cause undesirable effects. such as ringing or oscillation in high-speed amplifiers. For LM7171, a feedback resistor of 510Ω gives optimized performance.

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7 Device and Documentation Support

7.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

7.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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7.3 Trademarks

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7.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.5 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

8 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (September 2014) to Revision D (February 2024)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document	1
• Updated *Package Information*	1
• Deleted footnote from *Recommended Operating Conditions*	3
• Changed DC and AC specifications tables to *Electrical Characteristics: ±15V*	4
• Changed LM7171A unity-gain bandwidth from 200MHz to 160MHz	4
• Changed LM7171A settling time from 42ns to 16ns	4
• Changed LM7171 A Input-referred voltage noise from 14nV/√Hz to 8.5nV/√Hz	4
• Changed LM7171 A Input-referred current noise from 1.5pA/√Hz to 1pA/√Hz	4
• Changed DC and AC specifications tables to *Electrical Characteristics: ±5V*	6
• Changed LM7171A slew rate from 950V/µs to 1200V/µs	6
• Changed LM7171A phase margin from 57° to 68°	6
• Changed LM7171A settling time from 56ns to 15ns	6
• Changed LM7171A propagation delay from 6ns to 2.5ns	6
• Changed LM7171A input-referred voltage noise from 14nV/√Hz to 8.5nV/√Hz	6
• Changed LM7171A input-referred current noise from 1.8pA/√Hz to 1pA/√Hz	6
• Added new *Typical Characteristics* section for LM7171A	8
• Deleted second paragraph in *Slew-Rate Limitation*	24

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Changes from Revision B (March 2013) to Revision C (September 2014)	Page
• Changed data sheet flow and layout to conform with new TI standards. Added the following sections: Device Information Table, Application and Implementation; Layout; Device and Documentation Support; Mechanical, Packaging, and Ordering Information	1

Changes from Revision A (March 2013) to Revision B (March 2013)	Page
• Changed layout of National Data Sheet to TI format	25

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM7171AIM/NOPB	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	-40 to 85	LM71 71AIM
LM7171AIMX/NOPB	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(L71AIM, LM71) 71AIM
LM7171AIMX/NOPB.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(L71AIM, LM71) 71AIM
LM7171BIM/NOPB	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	-40 to 85	LM71 71BIM
LM7171BIMX/NOPB	Obsolete	Production	SOIC (D) | 8	-	-	Call TI	Call TI	-40 to 85	LM71 71BIM
LM7171BIN/NOPB	Active	Production	PDIP (P) | 8	40 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM7171 BIN
LM7171BIN/NOPB.A	Active	Production	PDIP (P) | 8	40 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM7171 BIN
LM7171BIN/NOPB.B	Active	Production	PDIP (P) | 8	40 | TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM7171 BIN

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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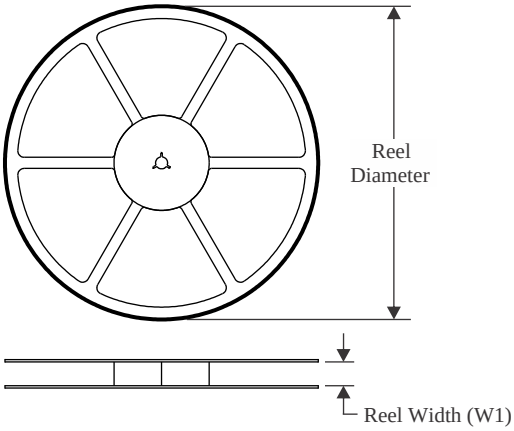
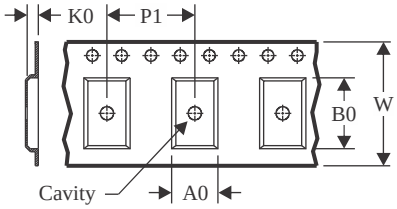
TAPE AND REEL INFORMATION

REEL DIMENSIONS

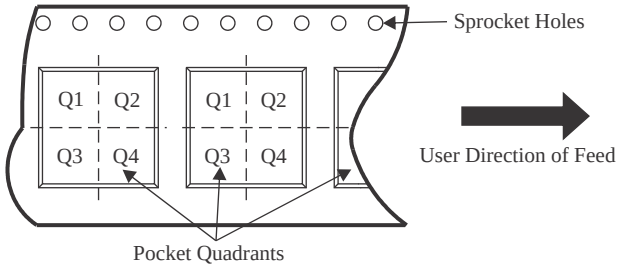


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

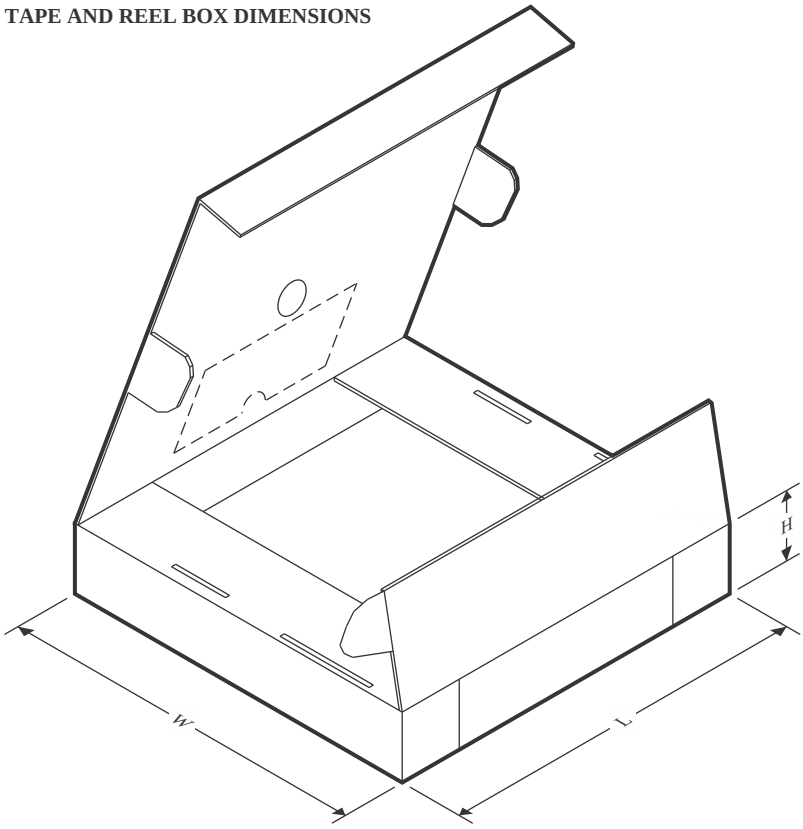
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM7171AIMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

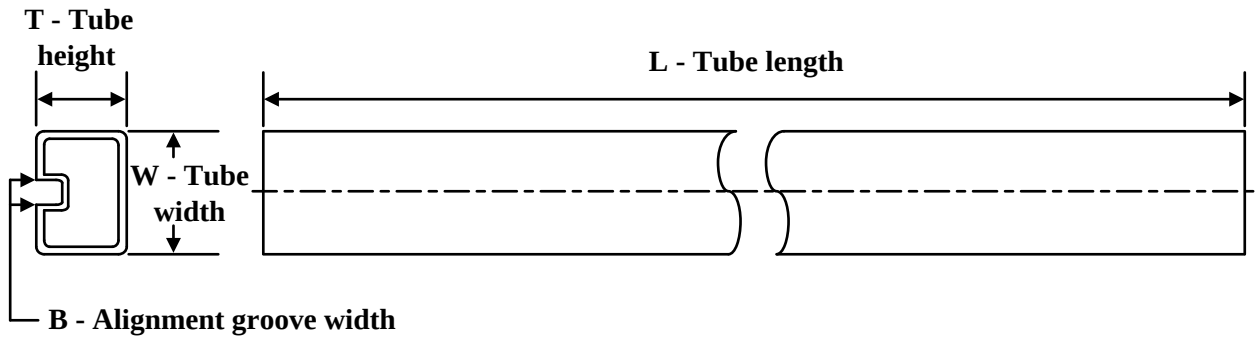
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

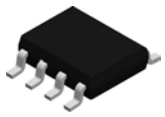
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM7171AIMX/NOPB	SOIC	D	8	2500	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM7171BIN/NOPB	P	PDIP	8	40	502	14	11938	4.32
LM7171BIN/NOPB.A	P	PDIP	8	40	502	14	11938	4.32
LM7171BIN/NOPB.B	P	PDIP	8	40	502	14	11938	4.32

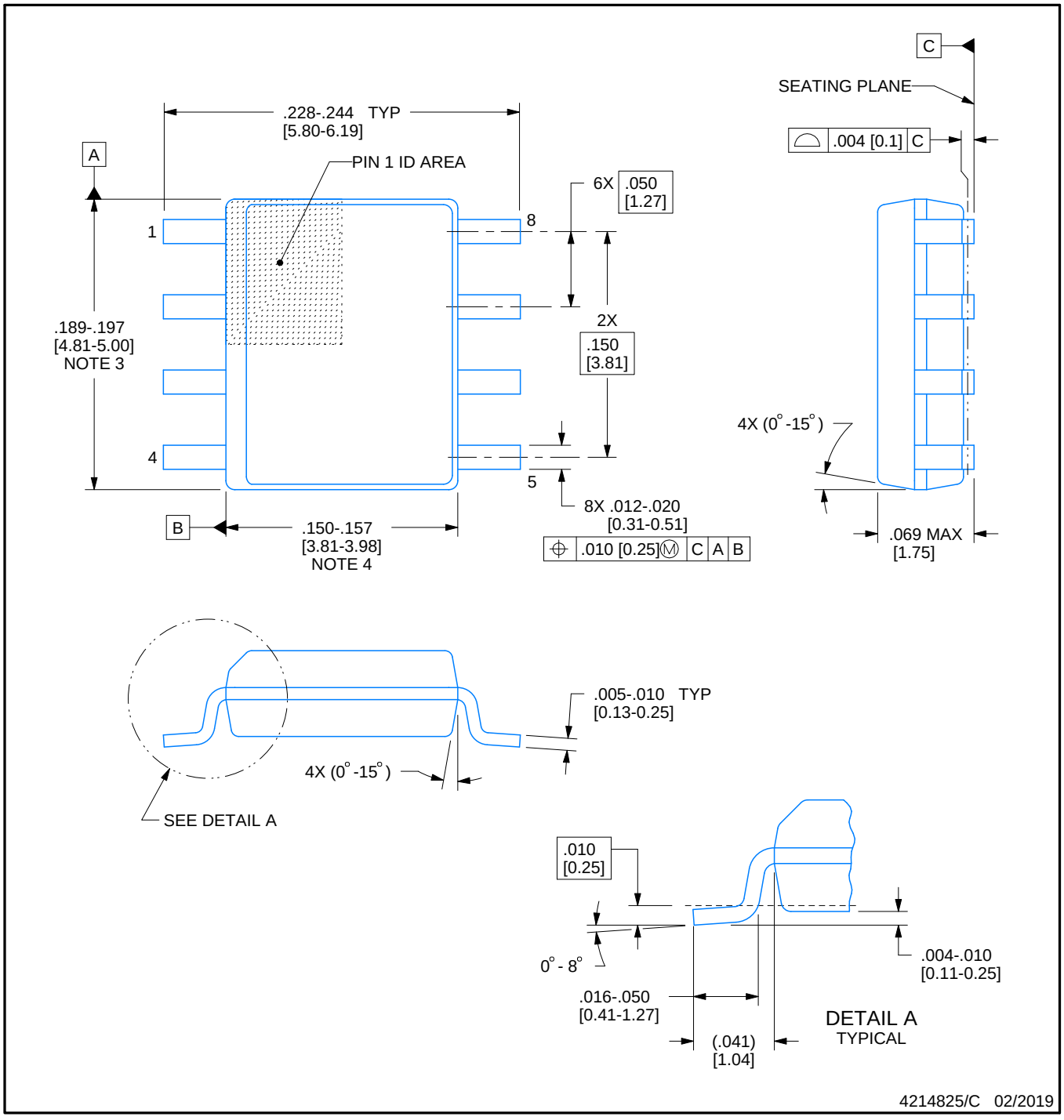


PACKAGE OUTLINE

D0008A

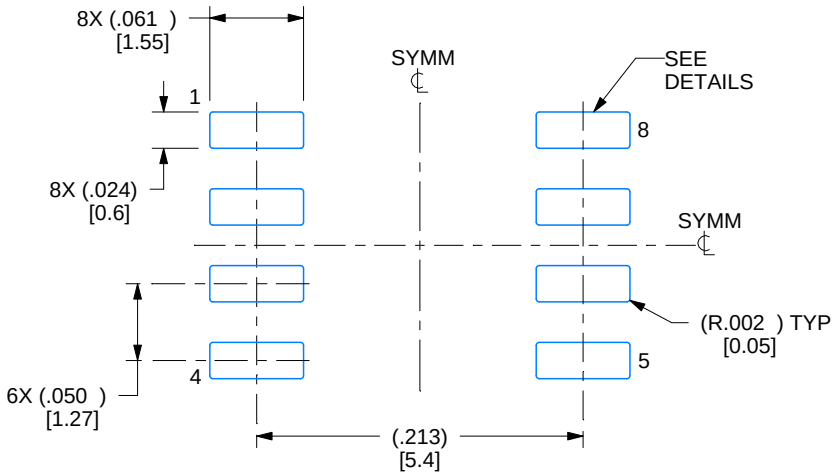
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

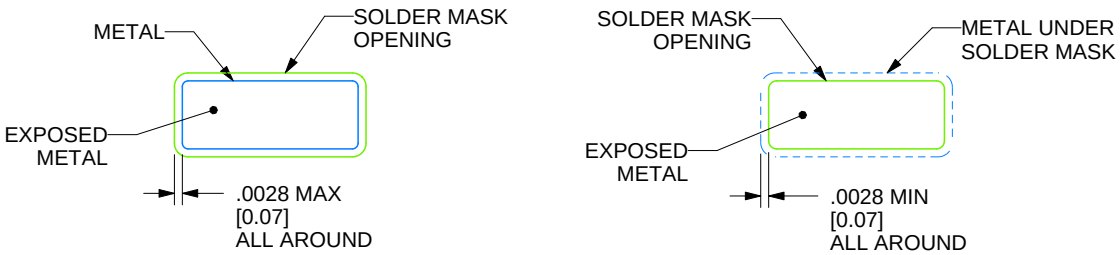


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

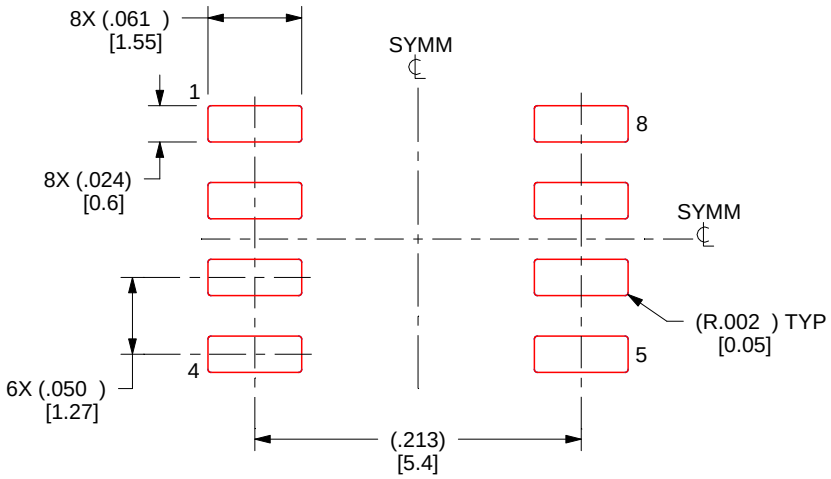
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



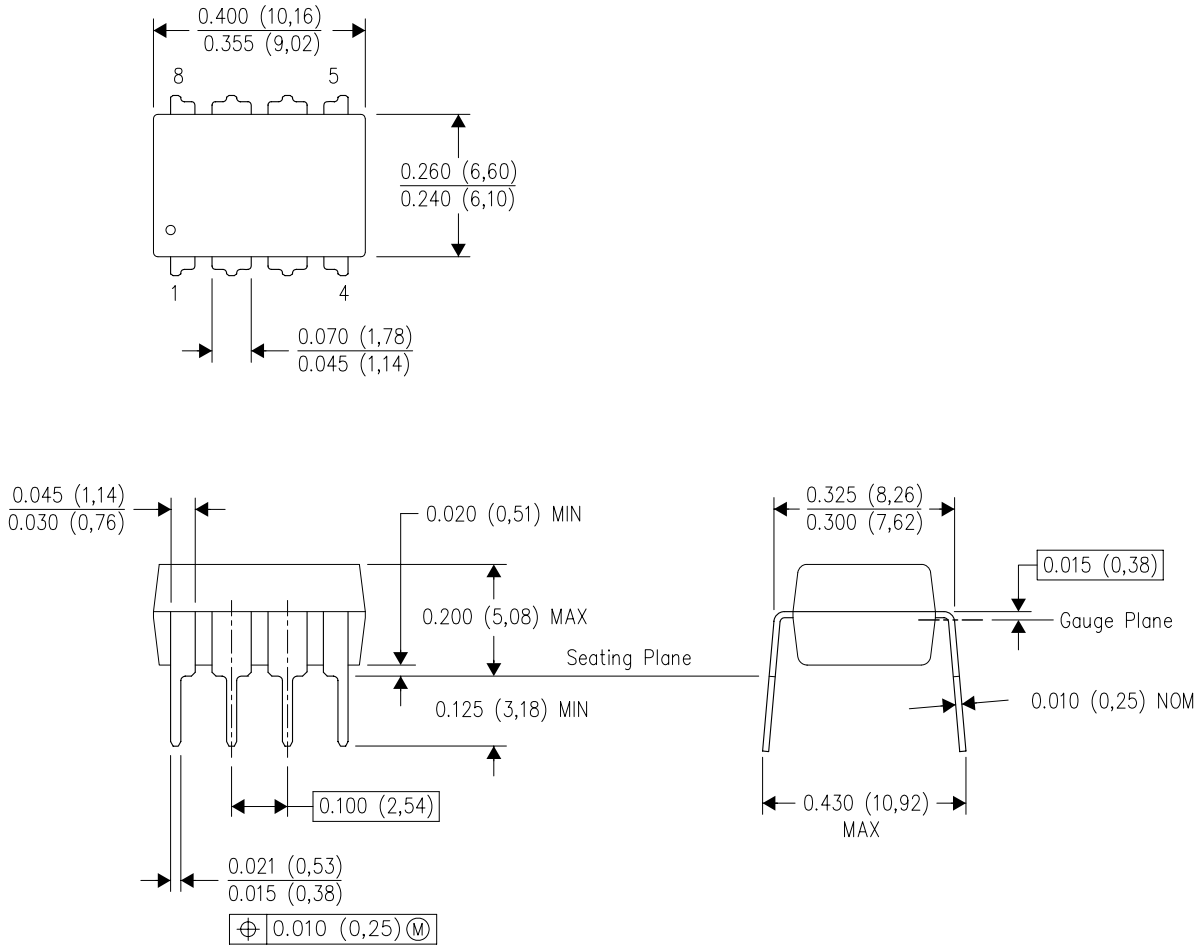
SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

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